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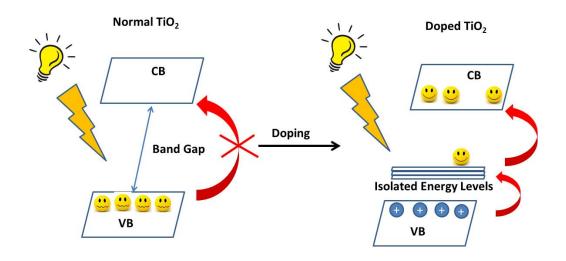
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Visible-Light Activation of TiO₂ Photocatalysts: Advances in Theory and Experiments

Vinodkumar Etacheri,^{1, 2} Cristiana Di Valentin,³ Jenny Schneider,⁴ Detlef Bahnemann,^{4,5} and Suresh C. Pillai ^{6, 7} *

In this review, advances in the strategies for improving the photocatalytic activity of TiO_2 under visible-light irradiation are discussed in detail. Effects of various techniques on the electronic structure and photocatalytic activities have been systematically investigated. Several theoretical insights and future recommendations are presented to enhance the performance of existing visible-light active TiO_2 .



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Visible-Light Activation of TiO₂ Photocatalysts: Advances in Theory and Experiments

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Abstract

The remarkable achievement by Fujishima and Honda (1972) in the photoelectrochemical water splitting results in the extensive use of TiO₂ nanomaterials for environmental purification and energy storage/conversion applications. Though there are many advantages for the TiO₂ compared to other semiconductor photocatalysts, its band gap of 3.2 eV restrains application to the UV-region of the electromagnetic spectrum ($\lambda \leq 387.5$ nm). As a result, development of visible-light active titanium dioxide is one of the key challenges in the field of semiconductor photocatalysis. In this review, advances in the strategies for the visible light activation, origin of visible-light activity, and electronic structure of various visible-light active TiO₂ photocatalysts are discussed in detail. It has also been showed that if appropriate models are used, the theoretical insights can successfully be employed to develop novel catalysts to enhance the photocatalytic performance in the visible region. Recent developments in the theory and experiments in visible-light induced water splitting, degradation of environmental pollutants, water and air purification and antibacterial applications are also reviewed. Various strategies to identify appropriate dopants for improved visible-light absorption and electron-hole separation to enhance the photocatalytic activity are discussed in detail, and a number of recommendations are also presented.

1. Introduction

Photocatalysis refers to the acceleration of a chemical reaction in the presence of substances called photocatalysts, which can absorb light quanta of appropriate wavelengths depending on the band structure [1-4]. Usually semiconductors including TiO_2 , Fe_2O_3 , WO_3 , ZnO, CeO_2 , CdS, Fe_2O_3 , ZnS, MoO_3 , ZrO_2 , and SnO_2 are selected as photocatalysts due to their narrow band gap and distinct electronic structure (unoccupied conduction band and occupied valence band) [5-24]. In semiconductor photocatalysis, electrons from the valence band of a semiconductor are excited to the conduction band by light of higher energy matching the band gap, resulting in e^{-}_{CB} / h^{+}_{VB} pairs (**Figure 1**). Conduction band electrons are good reducing agents (+0.5 to -1.5 V vs. NHE) whereas the valence band holes (h^{+}_{VB}) are strong oxidising agents

(+1.0 to +3.5 V vs. NHE) [25]. The lack of a continuum of inter-band states in semiconductors assures an adequately extended lifetime for photogenerated e^-_{CB}/h^+_{VB} pairs to initiate a redox reaction on the catalyst surface. Electrons in the conduction band can reduce O_2 to form superoxide radicals $(O_2^{\bullet^-})$. Additional reaction of $O_2^{\bullet^-}$ with holes on the valence band produce singlet oxygen (1O_2) [26, 27]. Subsequent reaction of valence band holes with surface adsorbed H_2O or HO^- result in the formation of hydroxyl radicals (HO^{\bullet}), hydrogen peroxide (H_2O_2), and protonated superoxide radical (HOO^{\bullet}). H_2O_2 in the valence band is reported to be resulting from the coupling of two HOO^{\bullet} [28, 29]. Further reaction of H_2O_2 with HO^{\bullet} to form protonated superoxide radical (HOO^{\bullet}) [4, 30].

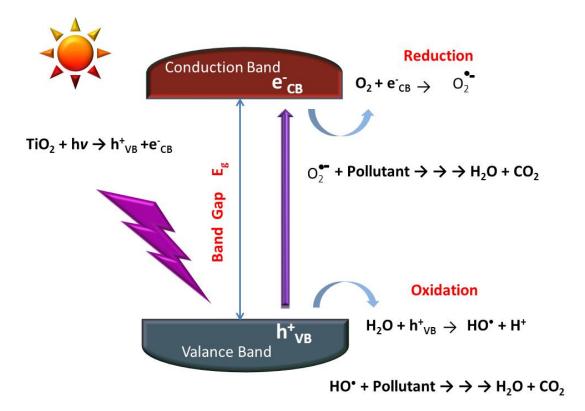


Figure 1. Mechanism of semiconductor photocatalysis. Reproduced with permission from ref. [4] Copyright 2015 Elsevier Science

During the photocatalytic process, free electrons/holes, and reactive oxidizing species (ROS) such as HO₂•, HO• and O₂• react with the surface adsorbed impurities including inorganic, organic compounds, and biological species (bacteria, virus etc.) leading to their decomposition. The efficiency of a photocatalytic reaction mainly depends on the capability of the photocatalyst to generate longer-lived electrons and holes that result in the formation of reactive free radicals. Usually, the crucial aspect is the creation and efficient utilization of the reactive oxidizing species (ROS). Semiconductor nanomaterials, especially TiO₂ find wide range of applications in the area of photocatalysis, pigments, dye sensitized solar cells, air/water sanitization, initiation of chemical reactions, optoelectronics, cancer therapy, cathodic protection of metals from corrosion, electrochromic displays, and light-activated antibacterial surfaces [6-8, 10, 11, 13, 17, 19, 31-46]. Currently, researchers all over the world are trying to improve the efficiency and selectivity of TiO₂ photocatalysts for various applications. Although a number of review papers and feature articles are published recently on the advances of TiO₂ photocatalysis [1-4, 7, 47-50], theoretical and experimental strategies for visible light activation have not been described comprehensively. To gain further insights into the development of next generation photocatalysts, it is highly desirable to condense the advances in experimental as well as theoretical approaches. Aim of this review is to summarize the progress in the experimental methods, theoretical approaches, and electronic structure modelling of TiO₂ for the visible-light activation. Several recommendations are also presented for improving the visible-light absorption and electron-hole separation of current generation TiO₂ photocatalysts.

2. Basic principles and mechanism of photocatalysis

2.1. Structural and electronic properties

The initial work of water decomposition using electrodes composed of TiO₂ was done by Fujishima and Honda [5]. They found that the photolysis of water into their individual constituents (H₂ and O₂) is greatly affected by the nature of surface defects. However, the quantum efficiencies of TiO₂ in solar energy conversions are rather poor due to faster recombination of electron-hole pairs [13, 51]. Since its invention in 1972, light-induced decomposition of organic species is the most vigorously investigated application of TiO₂ photocatalyst. For the first time, photocatalytic reduction of CN⁻ in aqueous solution was reported in 1977 by Frank and Bard [52, 53]. This investigation triggered the use of TiO₂ photocatalyst for water purification by exploiting solar irradiations [18, 54, 55]. Other noteworthy advances include the invention of dye sensitized solar cells by Gratzel et al, which is composed of titanium dioxide anodes and the discovery of anti-fogging abilities of TiO₂ surfaces by Wang et al. [33, 56] The extensive use of titanium dioxide for a wide range of applications over other photocatalysts results from its non-toxicity, abundance (inexpensiveness), thermal/chemical stability, and high redox potential [18, 57, 58]. Anatase (tetragonal), rutile (tetragonal), and brookite (orthorhombic) are three polymorphs of TiO2. Band gaps of anatase, rutile and brookite phases are 3.2, 3.0 and 3.4 eV respectively [59-61]. Wider band gaps are common for poorly crystallized nanoparticles and thin films, and a band gap narrowing up to 0.2 eV was observed for TiO₂ nanomaterials having 5-10 nm particle size. Anatase and brookite are meta-stable phases, and rutile is thermodynamically stable. Anatase and brookite TiO₂ irreversibly and exothermically converts to rutile at temperatures exceeding 600 °C [8, 10, 62, 63]. Due to superior mobility of electron-hole pairs, and improved surface hydroxyl density, anatase TiO₂ exists as the photocatalytically most active polymorph of TiO₂ [54, 64, 65]. In contrast, photocatalytic performance of rutile TiO₂ is not promising, and the activity of brookite phase is not systematically investigated [19, 66]. A number of factors, such as surface area, particle size, ratio of polymorphs, type of dopants, defect concentration, synthesis method, and phase purity, strongly affect the photocatalytic activity of TiO₂ [67-69].

The crystal structure of TiO_2 polymorphs can be explained by the different spatial arrangements of TiO_6 octahedra (Ti^{4+} ions bordered by six O^{2-} ions). The differences between three crystal structures are the various degrees of distortion and 3-D assembly of TiO_6 octahedra (Figure 2). In the anatase tetragonal crystal structure (a=b=3.78~Å, c=9.50~Å) each octahedron share corners to form (001) plane. Whereas tetragonal structure of rutile (a=b=4.58~Å, c=2.95~Å) consists of edge sharing octahedron (001) plane. Orthorhombic structure of brookite phase (a=5.43~Å, b=9.16~Å, c=5.13~Å) is made up of both corner and edge sharing octahedra. These different crystal structures result in various densities and electronic structure of the three TiO_2 polymorphs. Titanium dioxide usually exists as an n-type type semiconductor due to the presence of oxygen vacancies [70]. Photocatalytic activity of amorphous TiO_2 is negligible compared to that of crystalline TiO_2 [71, 72]. This is because the crystalline structure minimizes the photo excited electron hole recombination.

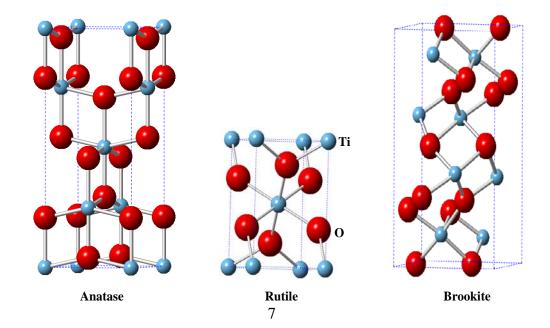
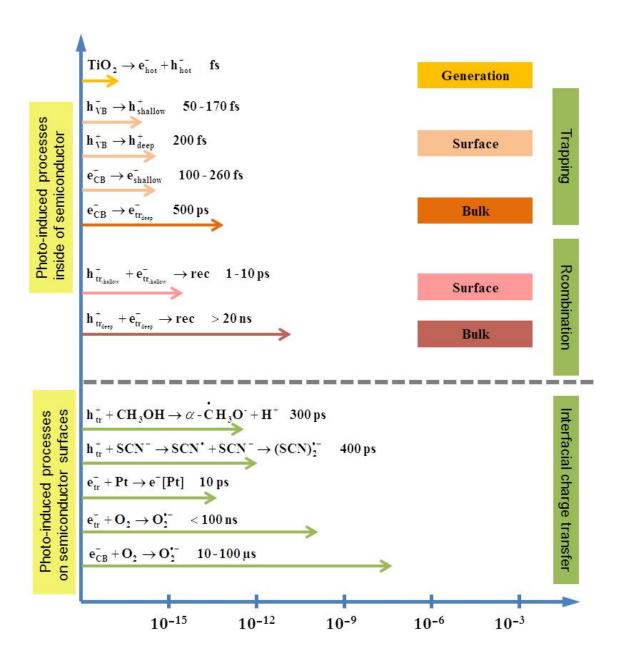


Figure 2. Crystal structure of anatase, rutile and brookite

2.2 Mechanism of photocatalysis

As described in the introduction part, illumination of TiO₂ with light waves of energy greater than its band gap results in the formation of electron-hole pairs. Hoffmann *et al.* proposed a general mechanism for TiO₂ photocatalysis based on the laser flash photolysis measurements [18]. Various steps in the mechanism with corresponding reaction times are presented in scheme 1. According to this mechanism, there exists nanosecond to picosecond competition between trapping and recombination of photogenerated electron-hole pairs.



Scheme 1. Various steps involved in TiO₂ photocatalysis. Reproduced with permission from ref. [3] Copyright 2014 American Chemical Society

The second type of competition (millisecond to microsecond) is between interfacial charge transfer and recombination of trapped species. The overall quantum efficiency of the photocatalytic process depends on the net effect of these competitions. The quantum efficiency of a photocatalytic reaction is expected to increase by increasing

the lifetime of electron-hole pairs and the interfacial charge transfer. This mechanism does not consider direct transfer of photogenerated holes.

However, it was assumed that hole-transfer occurs only through a surface trapped hole species or through the hydroxyl radical. This hypothesis was proved by the identification of hydroxylated compounds during the photocatalytic decomposition of halogenated aromatic compounds. Additionally, this study has provided evidence for the fact that hydroxyl radicals are the primary oxidizing species in photo-activated TiO₂ [73-75]. Electron paramagnetic resonance (EPR) spectroscopy also confirmed the formation of hydroperoxy (*O₂H) and hydroxyl radicals (*OH) during the illumination of aqueous TiO₂ suspensions [76-80]. Mao *et al.* investigated the kinetics of the hydroxyl radical mediated oxidation of chlorinated hydrocarbons. The strong dependence of the C-H bond strengths and the rate of oxidation confirmed the abstraction of H atom by *OH as the rate-determining step [81].

The rate of decomposition of pollutants were found to be highly dependent on its adsorbed concentration, which also implies that the hydroxyl radical concentration on the catalyst surface determines the reaction kinetics [82, 83]. On the other hand, the direct oxidation mechanism using valence band hole prior to trapping is also reported in the literature. Mao *et al.* reported the photo-Kolbe type oxidation of oxalic acid and trichloroacetic acid using TiO₂ valence band holes [81]. During the TiO₂ sensitized decomposition of potassium iodide, 2, 4, 5 trichlorophenol and thianthrene, products of the direct electron transfer oxidation reaction were observed, and they were unable to find evidence for hydroxyl radical reaction [84]. In addition, Experimental evidence for the hole-mediated decomposition of organic moieties such as acetate, glyoxylate, and formate on TiO₂ surface were also reported [85]. However, OH radicals and holes exhibited different regioselectivities in the photocatalytic oxidation of 4-

hydroxybenzyl alcohol (HBA) on ZnO and TiO_2 [86]. In addition to hole's and hydroxyl radical's, involvement of H_2O_2 in the photocatalytic decomposition of various inorganic and organic compounds was also found [87]. In this mechanism, highly reactive 'OH species are generated as a result of homolytic scission, or H_2O_2 act as an electron acceptor. In most of the photocatalytic reactions, two-electron reduction of oxygen results in the formation of H_2O_2 .

Similarly, Gerischer et al. identified oxygen reduction as the rate-determining step in semiconductor photocatalysis [88, 89]. Through ¹⁸O isotopic studies, Hoffman *et al.* proved that all hydrogen peroxide arises from dioxygen reduction using conduction band electrons and in the absence of oxygen, no H₂O₂ was detected [90]. They also proposed that hydroxyl radical bound on TiO₂ surface (TiOH^{•+}) acts as the principal oxidizing agent in the absence of O₂. Because of the more negative conduction band level of TiO₂ compared to hydrogen production level, (E_{H2/H2O}), photo-excited electrons can result in the water splitting to generate hydrogen. Photo-excited electron-hole pairs in TiO₂ can also destroy bacteria and other microorganisms. This happens due to strong redox reactions of the electron-hole pairs with proteins and amino acids, which are the building blocks of micro-organisms. Hashimoto and coworkers explained the mechanism of photokilling of E. Coli bacteria on nanocrystalline TiO₂ coatings [91]. They observed photodecomposition of bacterial cell wall due to the decay of lipopolysaccharide (LPS), which is the major constituent of the cell wall [92]. Recently, Pillai and co-workers reported the photocatalytic antimicrobial properties of partially crystalline nanotube TiO₂ bundles [93]. These nanotube materials were found to be highly effective in disinfecting both E. coli (97.53%) and S. aureus (99.94%). The high-aspect ratios of nanotubes (Figure 3) and presence of a large number of surface hydroxyl groups were reported as the reasons for high antibacterial activity.

It is thus clear that the antibacterial effect of TiO₂ is a bactericidal action (which involves decomposition of the cell wall), and not a simple bacteriostatic action. Photo-induced bacterial-killing mechanism on titanium dioxide surface has been also demonstrated by other studies [94-96]. In the first step, electron-hole pairs are created by the irradiation of light on the semiconductor surface. The reactive oxygen species (ROS), such as O₂•, ¹O₂, HO•, H₂O₂, and HO₂• formed by the reaction between electron-hole pairs and surface adsorbed H₂O, HO and O₂. Further reaction of these species results in the bacterial decomposition. Initially the reactive oxygen species attack the weak points of bacterial cell wall to leak the internal components, followed by the total decomposition of the damaged cells [93, 94, 96]. Observed rate of photokilling was low for micro-organisms having a cell wall. Those without a cell wall undergo fast photo-degradation due to direct attack of electron hole pairs on cytoplasmic membrane. Thus, photocatalysis can be used as a powerful tool for the destruction of micro-organisms [91, 92, 97].

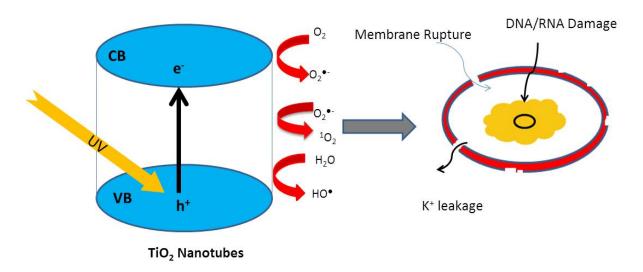


Figure 3. Schematic representation of bacterial photokilling using TiO₂. Reproduced with permission from ref. [93] Copyright 2015 Elsevier Science.

Zhang et al studied the mechanism of the OH radical production in anatase and rutile photocatalysts by employing two different probe molecules such as coumarin and coumarin-

3-carboxilic acid [98]. Rutile TiO₂ was found to produce smaller amount of OH radicals compared to anatase crystals (Figure 4). Hydroxyl radical formation on anatase TiO₂ surface was explained by the conversion of trapped holes. Whereas on rutile TiO₂ surface, Ti-peroxo (Ti-OO-Ti) formed by the combination of two trapped holes act as a catalyst to generate OH radical from water. They also concluded that conduction band reduction of H₂O₂ doesnot contribute towards OH radical generation [98]. These findings are very significant towards optimizing the photocatalytic activity of TiO₂ polymorphs for various applications.

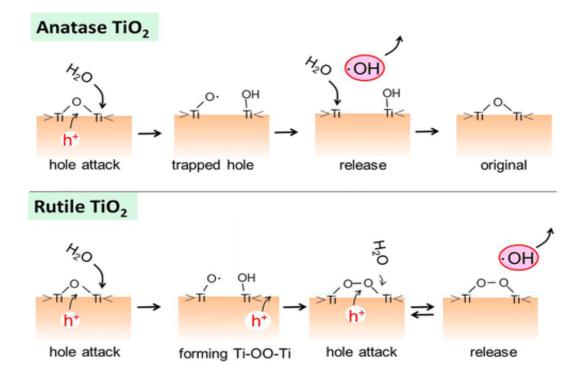


Figure 4. Scheme showing the mechanism of OH radical production with anatase and rutile. Reproduced with permission from ref. [98]. Copyright 2014 American Chemical Society

2.3. Limitations of TiO₂ photocatalyst

One of the main shortcomings of TiO₂ photocatalyst is the recombination of photogenerated charge carriers, which decreases the quantum efficiency of the overall

reaction [40]. Photo-excited electron come back to the valence band radiatively or nonradiatively during the recombination process [99-101]. This can occur either in the bulk or on the surface, which are normally induced by defects, impurities and other crystal bulk/surface imperfections [40, 102]. Trapping of the photo-generated electrons by the reduction of surface Ti⁴⁺ ions to Ti³⁺ species happens in ~30 ps, while the recombination occurs within 10 ns [102]. Many methods including heterojunction formation, doping with ions, and nanosized crystals have been demonstrated to reduce photo-excited charge carrier recombination [103-110]. For example, TiO₂ doped with Ag and Au exhibited superior photocatalytic activities [63, 111]. This was due to the fact that the metal nanoparticles act as electron traps during the photocatalytic reaction, and thereby decreasing the rate of electron-hole recombination. Additionally, the industrial TiO₂ Evonik Degussa P-25 is a mixture of 30 % rutile and 70 % anatase, which exhibited notably higher photocatalytic activities compared to other phase-pure TiO₂ samples [112]. Superior photocatalytic activities of these biphasic TiO₂ resulted from the efficient transfer of electron from the conduction band of anatase to those of rutile TiO₂. Notably, higher visible-light induced photocatalytic activities of N-doped, and S, N-codoped anatase-rutile nanoheterojunctions are reported by Etacheri et al [11, 17]. They explained details of electronic structure of these heterostructure photocatalysts, and attributed superior photocatalytic activities to the efficient transfer of photogenerated electrons from the conduction band of anatase to that of rutile. In conclusion, any factor increasing the life-time of electron-hole pairs can substantially increase the photocatalytic performance and quantum efficiency of TiO₂ photocatalysts.

Poor thermal stability of the photocatalytically most active anatase phase is another main disadvantage of TiO₂ photocatalyst. Anatase TiO₂, the most

photocatalytically active polymorph, is thermally less stable and undergoes irreversible transformation to the less active rutile phase occurs above 600 °C [10, 113]. This confines the high temperature (\geq 700 °C) applications including ceramic materials. The anatase to rutile transformation (ART) is slow below 600 °C and extremely rapid above 700 °C. The transformation involves co-operative movement of the individual O^{2-} and Ti^{4+} ions. During ART, two Ti-O bonds of the anatase crystal structure (edgeshared) to form a corner shared rutile structure (Figure 5) [113-116]. As mentioned in the introduction part (section 1), both rutile and anatase have tetragonal crystal structure and previous reports proved that the kinetic stability of anatase is higher than that of rutile under ambient conditions.

Rutile is a thermodynamically more stable phase than anatase. The thermodynamic phase stability calculation by Banfield and co-workers demonstrated that a critical particle-size of around 14 nm is required to initiate anatase to rutile transformation [117, 118]. Anatase phase is more stable below this critical size [10]. Activation energy of 90 Kcal/mol is required for the transformation, which follows first order kinetics. Creation of lattice vacancies through removal of oxygen ions accelerates ART. The transformation temperature depends on several factors such as (a) impurity content (b) reaction atmosphere (c) particle size and its morphology (d) degree of agglomeration and (e) synthesis method of anatase TiO_2 . Another serious drawback of the TiO_2 photocatalyst is the wide band gap of anatase TiO_2 ($E_{bg}\sim 3.2$ eV), which restrains its use to UV light ($\lambda \leq 390$ nm) [8]. Because of this, TiO_2 displays a high photocatalytic activity only when it is irradiated by UV light. Even though the absorption onset of high temperature stable rutile phase ($E_{bg}\sim 3.0$ eV) occurs around 413 nm, its performance is restricted due to mediocre redox potential, and faster recombination of electron-hole pairs [66]. This means that only ~ 5 % of the solar

radiations can be utilized by the conventional TiO₂ photocatalyst, which adversely affect the commercialization of TiO₂ based photocatalysts [17, 119]. It is crucial to develop visible-light active TiO₂ to effectively exploit solar-radiations or other artificial lights. Studies begin in the 1980s to synthesize narrow band-gap titanium dioxide that can absorb and efficiently utilize both UV (290-400 nm) and visible (400-700 nm) light. Various techniques employed for the visible light activation are explained in detail in the following sections.

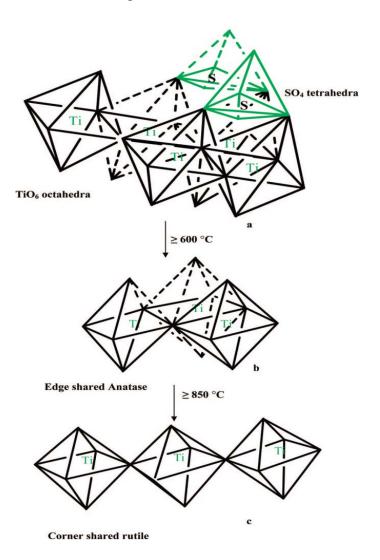


Figure 5. The schematic representation of transformation of edge shared anatase photocatalysts to corner shared rutile from a titanyl oxysulfate precursor. Reproduced with permission from ref. [113] Copyright 2008 American Chemical Society

3. Advances in the theoretical approaches to model photocatalysts and their photoactivity

Theory can be applied to investigate various aspects of the photocatalytic cycle; in particular, the light absorption process, the electron/hole transport in the bulk and their migration to the surface, the band edge alignments of semiconductors, and surface photo-redox chemistry, just to cite the most relevant ones. If accurate methods and models are used, the theoretical insights can be fruitfully used to improve the photocatalytic performance, especially in the range of visible-light.

3.1 Photocatalysts electronic structure

Density functional theory (DFT) has gained a prominent position in the general scenario of computational materials science thanks to its rather high accuracy at a relatively low cost. This applies also to the case of materials for photocatalysis (e.g. TiO₂), where the accurate description of the electronic structure is crucial in order to correctly understand and foresee their interaction with light and the photo-response. However, standard DFT approaches, such as LDA and GGA methods, suffer of the residual electron self-interaction and an improper description of electron correlations causing the well-known underestimation of the band gap and excessive delocalization of the dopant induced states. Two pragmatic approaches for the correction of self-interaction are the hybrid density functional methods, which include a fraction of exact (Hartree-Fock type) exchange, and the DFT+U methods, where an on-site Hubbard U electron repulsion is added on selected localized orbitals. These methods presented a better explanation of the fundamental gap but also of the location of the impurity-states induced by the presence of the dopants in the band-gap of TiO₂, which is critical for the in the visible light absorption process.

Hybrid density functionals, with a typical 20–25% contribution of exact exchange, overestimate the TiO₂ band gap. A reduction of this contribution to 12–15% makes the Kohn-

Sham gap match the experimental fundamental gap. With the DFT+U method, very large and unphysical U values (U = 6 eV) for the on-site correction on Ti 3d states are required to reproduce the experimental band gap, whereas the use of the self-consistent linear response derived U values (U = 3.23 eV for anatase and U = 3.25 for rutile) only slightly improves the GGA band gap [120]. Such values are anyhow better suitable for the correct description of the electronic modifications induced by the dopants.

3.2 Doped and Defective Photocatalysts

The visible light activation of photocatalysts is often the result of electronic structure engineering of materials through doping or defectivity. These approaches cause the modification of the band structure or the introduction of new defect states in the photocatalyst band gap, whose correct position and description are not easily obtained by the ground state DFT calculations. It is common practice to estimate the semiconductor band gap and the energy levels introduced in the gap by defect centers using single-particle Kohn-Sham eigenvalues. This approach, however, is not well justified and can be used only for qualitative comparisons with optical or photoemission experimental data. The problem of the position of defect states in the gap can be partly solved by the calculation of the "transition energy levels" between different charge states of the (intrinsic or extrinsic) defect under investigation. These quantities (commonly referred to as ε^{opt} or ε^{therm} , for optical and adiabatic transitions, respectively) are obtained from total energy calculations and converted into formation energy of the defect in a specific charge state. This approach is analogous to the delta-selfconsistent-field method which allows to compute electronic excitations in finite systems from total energy differences. The transition energy levels (Figure 6) formalism provides a rigorous framework for computing then excitation and emission energies in doped or defective semiconductors that can be directly compared with experiments [121, 122]. Many successful

examples of the use of transition energy levels to rationalize optical and photocatalytic properties of materials already exist in the literature [123-131].

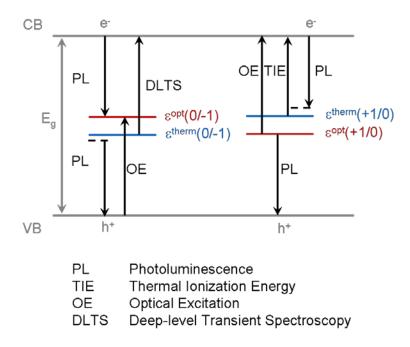


Figure 6. Schematic representation of electronic transitions in doped or defective semiconductors in relation with the spectroscopic techniques which can probe them. The \uparrow arrows indicate an electron excitation, the \downarrow arrows indicate an electron decay. ϵ^{therm} and ϵ^{opt} are defined with respect to the valence band maximum for (0,-1) and (+1,0) charge state transitions. Reproduced with permission from ref. [121] Copyright 2014 American Chemical Society

3.3 Photocatalysts light-induced excitation

To compute excitation energies, one should go beyond DFT, either through many-body perturbation theory (MBPT), in the GW approximation and the Bethe-Salpeter equation, or the time-dependent DFT (TD-DFT) method. A number of studies on bulk TiO₂ have recently appeared in the literature [123, 124, 132-134]. However, these approaches are still either too costly or not sufficiently accurate for extended systems, particularly if exposing surfaces. A more simplified approach to simulate the photoexcited TiO₂ is based on spin-constrained DFT,

where the first excited state is obtained by imposing a triplet spin state configuration to the model system [135]. Structural relaxation in the excited state is then achievable (not possible with any other more sophisticated method), which allows one to compute the emission energy from a self-trapped exciton. Comparison of the computed with the experimental luminescence values is excellent (2.6 vs. 2.3 eV), especially considering the inherent approximations [136]. The same approach can be used to describe separated electron/hole pairs, travelling from the bulk to the surface where they become self-trapped. Self-trapping energies are interesting quantities since they define how surface traps are competitive with respect to electron or hole transfers to chemical adsorbates, which are the first chemical step of any redox process in the photocatalytic cycle.

3.4 Redox processes at the photocatalysts surface

Photoinduced electrons and holes are generally considered to travel from the bulk to the surface. Recently, the driving force for this migration has been determined to be the larger trapping energy at a surface rather than a bulk regular site [135]. Chemical species adsorbed on the surface are excellent scavengers for electrons and holes. The O₂ molecule is found to very easily remove the electron from the catalyst to form first superoxo and then peroxo species (Figure 7) [137].

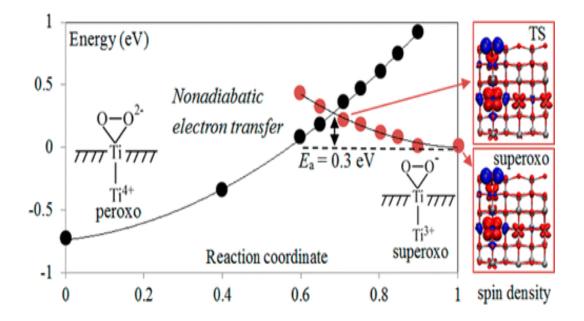


Figure 7. Schematic diagram showing the transfer of electron from a reduced TiO₂ surface to oxygen molecule. Reproduced with permission from ref. [137] Copyright 2013 American Chemical Society

Organic acids and alcohols were also computed to be excellent hole scavengers, which is a hint that the direct oxidation mechanisms is a viable path for certain chemical species [138]. Hydroxyl species are found to facilitate photo-oxidation reaction of methyl chloride on rutile (110) surface [139].

4. Historical developments of visible-light active TiO₂ photocatalysts

As discussed earlier, one of the major drawbacks of pure TiO_2 is the large band gap implying that this material can only be activated using an irradiation with photons in the UV region ($\lambda \leq 387$ nm). In order to obtain activity in the visible region, it is essential to modify the semiconductor materials by using dye sensitisation, noble metal doping, transition metal addition and non-metal doping. Modification with transition metal ions was the first method reported for their visible-light activation of TiO_2 [140]. The main drawback of these catalysts is the formation of recombination sites for photogenerated charge carriers and thus lowering the quantum efficiency. Transition metals also block the active surface reaction sites. In 1986 Sato discovered that modification of TiO_2 with NH₄OH resulted in their visible light absorption [141]. Later Asahi *et al* for the first time investigated the photocatalytic activity of N-doped TiO_2 [142]. After this report, significant efforts have been devoted for the development of various anion doped TiO_2 photocatalysts [143, 144].

4.1. Dye-sensitization

This is one of the widely used techniques for the utilization of visible-light in photocatalytic and photovoltaic systems [145-148]. During visible-light irradiation, excited electrons are transferred from the dyes to the conduction band of the semiconductor (Figure 8). Some dyes are even capable of producing electrons by absorbing visible-light in the absence of semiconductors. Nevertheless, in the absence of semiconductor charge separators, photocatalytic activities of these dyes are too low. Visible-light absorption and electron transfer to the conduction band of TiO₂ often resulted in a superior photocatalytic activity. Degradation of the dye itself is one of the main issues in the dye-sensitization of semiconductors. This was usually overcome by dye regeneration by using sacrificial agents, or redox systems like EDTA and I₃/I pair [149]. Optimum conditions to obtain higher photocatalytic efficiencies are fast electron transfer to the semiconductor and slow recombination. In the case of dye-sensitization, electron injections occur in a femtosecond scale compared to the recombination of electron-hole pairs in nanoseconds to milliseconds scale [150-154]. Advantages of the dye-sensitized photocatalytic reactions are the fast injection of electrons to the semiconductor and slow backward reaction. Visible-light induced hydrogen generation through dye-sensitized water splitting was reported by previous researchers [155, 156]. These studies illustrated that the electron injection occurs only from the dye molecules adsorbed on the surface of the photocatalyst. Dye-sensitization was also identified as highly effective for the degradation of a number of pollutants under visible irradiation [157, 158].

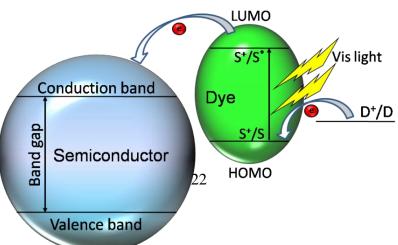
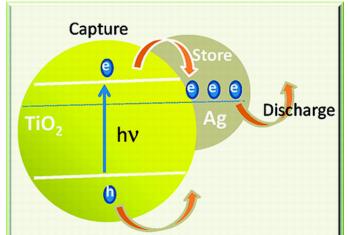


Figure 8. Mechanism of dye sensitized semiconductor photocatalysis

4.2. Noble metal loading

Noble metals for instance Au, Ag, Pt, Pd, and Rh have been reported as very efficient dopants for the visible-light activation and thereby improving the performance of TiO₂ photocatalysts [159-164]. Fermi levels of these noble metals are lower than that of TiO₂, which results in the effective transfer of the photogenerated electrons from the conduction band of TiO₂ to metal particles (Figure 9) [165]. This electron trapping process significantly reduces the electron-hole recombination rate, which results in stronger photocatalytic reactions. Electron spin resonance (ESR) spectroscopy was used by previous researchers to investigate the charge transfer mechanism in these metals doped TiO₂ [166]. Anpo and Takeuchi employed electron paramagnetic resonance (EPR) spectroscopy to establish electron transfer between Pt nanoparticles and TiO₂ [167]. Bamwenda *et al.* investigated the effect of Au and Pt nanoparticles on the photocatalytic activity of TiO₂ materials through the photocatalytic splitting of water-ethanol mixture [160]. Seery *et al.* improved the visible-light photocatalytic activity of TiO₂ by silver doping. They observed superior UV, and Vis-light absorption

due to silver plasmon [168].



resonance

Figure 9. Electron transfer mechanism in silver loaded TiO₂. Reproduced with permission from ref. [165] Copyright 2011 American Chemical Society

A number of synthetic methods including sol-gel process, hydrothermal method, impregnation, and photo-deposition were reported for the fabrication of noble metal modified TiO₂ [168-170]. Photocatalytic activities of these modified samples were highly dependent on both the synthesis method and work function of the noble metal. Among the various noble metal modified TiO₂ samples, Pt and Au loaded were found to be most effective and less sensitive to the synthesis methods. The higher effectiveness resulted from the higher work-functions and optimum electron-affinity associated with Pt and Au. Sakthivel *et al.* studied the photocatalytic activities of Au, Pt, and Pd modified TiO₂ through photo-oxidation of acid green-16 and determined the optimum loading for each metal [161]. Reduced photocatalytic performance was identified above an optimum metal content, which was proven to be as a result of reduced photon absorption by TiO₂ and action of excess metal as electron-hole recombination centers. The noble metal loaded TiO₂ photocatalysts shows also different photocatalytic activities for hydrogen production depending on the noble metal and sacrificial regent.

Recently, TiO₂ loaded with metallic nanoparticles possessing unique properties, such as localized surface plasmon resonance (LSPR), are widely used for

photocatalytic reactions in visible wavelengths [165, 171]. Modification of semiconductor nanostructures with plasmonic metal-nanoparticles improved the efficiency of water splitting, decomposition of organic compounds, and photovoltaic devices (by 10–15 %) [171-175]. For instance, Tian *et al.* reported superior visible-light photocatalytic decomposition of methanol and ethanol on Au-nanoparticles loaded TiO₂ films [176, 177]. Furube *et al.* used transient absorption spectroscopy for the investigation of charge separation/recombination dynamics in Au-nanoparticles loaded TiO₂ [178]. Their results proved plasmon induced electron transfer to TiO₂. Efficient utilization of the near IR radiations and photoelectric conversion by Au-nanorod arrays modified TiO₂ single crystals were reported by Nishijima *et al.* [179] It was found that a thin coating of silica on Au nanoparticles (Figure 10) significantly improved the photocatalytic rate by reducing the carrier recombination [180].

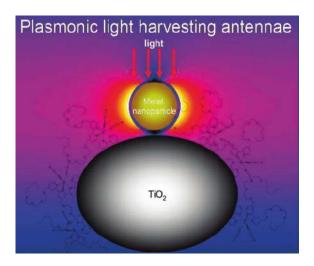


Figure 10. Plasmonic light harvesting using core-shell metal-insulator nanoparticles. Reproduced with permission from ref. [180] Copyright 2011 American Chemical Society

Plasmon sensitization was also used in combination with dye sensitization. For instance, addition of Ag nanoparticles increased the absorption coefficient and efficiency of dye-sensitized solar cells [180, 181]. Similarly, Rand *et al* modified the tandem solar cells with Ag-nanoparticles and observed an unexpected improvement in

the charge generation and visible-light absorption [182]. They attributed the surface plasmon modes of Ag-nanoparticles to the increased photocurrent generation. In addition, a number of studies demonstrated the superior plasmon-sensitized visiblelight photocatalytic activities of TiO₂ loaded with Au and Ag nanoparticles [183-185]. Several methods for silver nanoparticle deposition on TiO₂ such as thermal evaporation, magnetron sputtering, electrochemical deposition, hydrothermal treatment and photocatalytic reduction have been demonstrated by previous researchers [186-191]. In addition to Au and Ag nanoparticles, TiO₂ nanotube arrays sensitized with Pd nanoparticles highly efficient towards the visible-light induced were photoelectrocatalytic water splitting [192].

LSPR improves the photocatalytic activity in three different ways by; (1) extending light absorption of semiconductor to longer wavelengths, (2) increasing the scattering of visible-light, and (3) creating electron-hole pairs by transferring the electrons from the metal nanoparticles to the conduction band of semiconductors. When the semiconductor and plasmonic metal nanoparticles are in direct contact, direct electron transfer (DET) results from the metal to the conduction band of the semiconductor [183, 193, 194]. The critical factor deciding the feasibility of DET is the arrangement of the plasmonic metal Fermi level and semiconductor band levels. Consequently, if the electronic energy levels match, metal to semiconductor transfer of holes or electrons can occur even at energies below the band gap. Previous researchers confirmed LSPR mediated transfer of electrons from gold nanoparticles to the conduction band of TiO₂ [185]. Recent studies proved that the photocatalytic activity improvement was unchanged even after an insulating layer was added between the semiconductor and plasmonic metal [183]. As a result, it was concluded that electron-

hole pairs are created on the semiconductor by a radiative contribution of the LSPR-mediated local electromagnetic field (LEMF) [172, 174, 195].

4.3. Transition metal doping

Improved visible-light photocatalytic activities of various transition metal doped TiO₂ has been comprehensively investigated [196-202]. These studies proved that doping results in the increased visible-light absorption. As a result of transition metal doping, impurity energy levels are created in the band gap, which results in visible-light absorption. Photocatalytic activities are also improved by electron transfer between TiO₂ and transition metal ions [203]. Choi et al. doped TiO₂ with 21 transition metal ions and investigated their photocatalytic activities [196]. Visible-light photo-responses were observed for TiO₂ photocatalyst as a result of most of these metal ion doping. Extensive research on the enhancement of TiO₂ photocatalytic activities has been performed through doping of transition and rare earth metal ions, especially for air and water sanitization applications [196-198]. Among the various metal ions studied by Choi et al., increased photocatalytic activity was identified for Mo, V, Re, Ru, Fe, Rh, and Os ions doped TiO₂ [196]. Whereas Al and Co ions reduced the activity. Fe and Cu ions create additional energy levels near the valence band as well as conduction band of TiO₂, which result in the trapping of both electrons and holes. Consequently, it is highly recommended to dope TiO₂ with either Fe or Cu ions to obtain superior photocatalytic activity [196, 197].

Hashimoto *et al.* designed and fabricated Cu(II) and Fe (III) grafted TiO₂ photocatalysts for efficient visible-light induced decomposition of 2-propanol to CO₂ via acetone [204, 205]. In this case, visible-light activation was caused by the interfacial charge transfer from the valence band holes to Cu(II) ions. Cu(I) ions formed by the reduction of Cu(II) also act as a multi-electron oxygen reduction

catalyst. Reaction rates of Cu(II)/TiO2 catalyst was 2.1 fold higher than those of Ndoped TiO₂ under similar experimental conditions [204]. Fe(III)-grafted rutile TiO₂ displayed optical absorption in the visible region above 400 nm, which resulted from the interfacial charge transfer from the valence band of TiO₂ to the surface Fe(III) species [205]. Superior quantum efficiency of 22% was observed for Fe(III)/TiO₂ in the visible-light region (400-530 nm), and photocatalytic activity can be maintained up to 580 nm with a quantum efficiency of 10%. High performance of Fe(III)/TiO₂ was attributed to the accumulation of photogenerated holes in the valence band of TiO₂ and the catalytic reduction of oxygen by photoreduced Fe(II) species on TiO₂ surface (Figure 11). Morikawa et al. loaded N-doped TiO₂ with Fe, Cu and Pt to improve the visible-light response [206]. It was found that Pt, Fe and Cu loading resulted in similar rate enhancement towards acetaldehyde oxidation, while Pt, and Cu gave the highest rate for toluene and acetic acid oxidation. Rate of formic acid oxidation was enhanced by factors of 5 and 22 on loading Fe and Pt respectively. Extremely high rate enhancement of formic acid oxidation was attributed to the combined effect of photocatalysis and thermal catalysis. Such transition metal loading of N-doped TiO₂ was also reported by other researchers for the improved visible-light activation of TiO₂ [207].

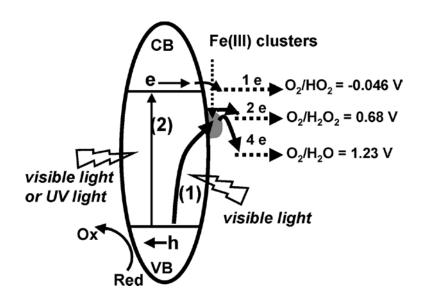


Figure 11. Schematic diagram illustrating the possible photocatalytic mechanism of Fe(III)/TiO₂ involving interfacial electron transfer and multielectron oxygen reduction. Reproduced with permission from ref. [205] Copyright 2010 American Chemical Society

Peng et al. investigated the photocatalytic activity of Be doped TiO₂ [208]. They found that metal ion doping close to the surface improve charge carrier separation, whereas deep doping accelerate carrier recombination. These findings were in good agreement with the results of Choi et al. [196]. Wu et al. investigated the effects of transitional metal ions (Cr, Mn, Fe, Co, Ni and Cu) doping on the photocatalytic activity of TiO₂ through the photocatalytic oxidation of acetic acid [201]. Enhanced photocatalytic activities were observed for Cu, Mn and Fe ions doped TiO₂ as they can trap electrons as well as holes, whereas Cr, Co and Ni ions doped samples were not much active as they can trap only one charge carrier. Dhanalakshimi et al. investigated the dye sensitized hydrogen production efficiency of Cu-modified TiO₂ and compared with that of Pt-doped compositions and the enhancing effect was found to be comparable [146]. Hydrogen production efficiency of Cu-modified TiO₂ particles from methanol solution were also investigated by Wu and Lee [209]. A ten-fold enhancement in the hydrogen production efficiency was demonstrated at an optimum Cu-loading. Xu et al compared photocatalytic activities of various (La, Ce, Er, Pr, Gd, Nd and Sm) rare earth metal ion doped TiO₂ [199]. TiO₂ loaded with optimum dopant content demonstrated superior band-gap narrowing and visible-light photocatalytic activities. As a result of its ability to transfer both electrons and holes to the surface Gd-ions doped TiO₂ was found to be the most photoactive.

Another efficient method for improving the visible-light response is metal ion implantation [167, 210, 211]. This process involves bombarding a semiconductor with

high-energy transition metal ions. During the collision, metal ions penetrate into the semiconductor crystal structure and improve the visible-light absorption by creating additional energy levels. A visible-light response up to 600 nm has been reported for metal ions implanted TiO2. Takeuchi et al. employed this method to implant Cr ions in TiO₂ thin films for the visible-light induced degradation of nitric oxide (NO) [210]. For this implantation, they used an ionized cluster beam (ICB). The UV-Vis absorption studies revealed the band gap narrowing in these TiO₂ samples and the extent of band gap narrowing was found to be directly proportional to the Cr-ion loading. Visiblelight photocatalytic activities of these Cr-doped TiO₂ were highly promising for NO degradation. This high activity compared to the chemically Cr-doped TiO₂ point towards the fact that metal ion implantation did not create recombination centers. A wide range of ions of metals (V, Cr, Mn, Ni, Mg, Ti and Fe) has been implanted for visible-light activation of TiO₂ [167, 211]. Visible-light absorption was observed for all ions except Mg and Ti ions. The effectiveness of dopant ions in the band gap narrowing was found to be in the following order: V > Cr > Mn > Fe > Ni. In the case of ion implanted TiO2 no sacrificial agents and electron mediators are necessary to maintain the reaction cycles. For improved carrier transferring and photocatalytic activity, metal ions should be doped close to the TiO2 surface. In the case of deep doping, carrier (electrons and holes) transfer to the interface is more difficult and metal ions act as recombination centers. Similarly, photocatalytic activity decreases above an optimum metal ion doping due to increased carrier recombination.

Metal doping of TiO_2 has been investigated theoretically in order to establish how the doping element effectively modifies the semiconducting oxide electronic structure for the absorption in the visible and the molecular adsorption properties at the surface [212-215]. In most of the cases the dopant is a transition metal in a

substitutional lattice cationic site. The correct description of the metal d states, especially when these are partially occupied, requires the use of methods, which reduce the electron self-interaction problem. For the case of Cr-doped TiO₂, GGA calculations indicate a spurious half-metallic character of the system (no splitting of the partially occupied Cr t_{2g} d states), contrarily to the semiconducting properties (splitting of the occupied-unoccupied Cr t_{2g} 3d states) by hybrid functional methods [216]. The presence of transition metal d states in the TiO₂ band gap is clearly the origin of the experimentally observed red-shift in the absorption properties of metal doped TiO₂ [217].

4.4. Heterojunction semiconductors

Coupling of semiconductors having different band gap values is another method to efficiently utilize visible-light and enhancing the photocatalytic activity. The necessary condition for coupling is that the conduction band level of at least one of the semiconductors must have a more negative value compared to the other. The electron injection mechanism in composite semiconductors can occur through the following mechanism (Figure 12). In the case of semiconductor heterojunctions, photogenerated electrons can be effectively transferred from the conduction band of one semiconductor to that of the other. The electron injection always occurs from the more negative conduction band to the less negative one. This electron transfer is identical to the dye sensitization of TiO₂, except the difference being the electron injection happens between two semiconductors. Coupling of TiO₂ with CdS (band gap 2.4 eV) and SnO₂ (band gap 3.5 eV) for visible-light induced water splitting and purification were previously investigated [145, 218, 219].

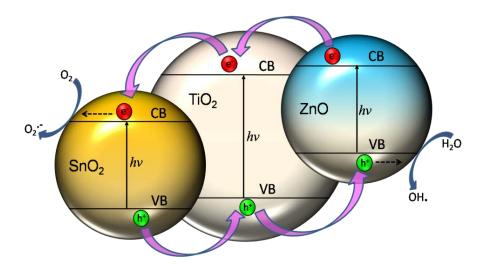


Figure 12. Electron transfer mechanism in composite semiconductor

In this case, the small band gap CdS (CB = -0.76 eV) cause visible-light sensitization, and inject electrons to the conduction band of SnO_2 (CB = -0.34 eV), which results in an efficient electron-hole separation and an increase of photocatalytic activity. EDTA was used as a hole scavenger to prevent the photo-corrosion of CdS. Doong *et al.* reported very high photocatalytic activity of CdS coupled TiO_2 towards the photocatalytic decomposition of 2-chlorophenol [220]. The better photocatalytic activity resulted from the electron injection from CdS to TiO_2 and hole injection from TiO_2 to CdS, which results in better charge separation. Kang *et al.* demonstrated the photodegradation of 4-chlorophenol using CdS- TiO_2 composite semiconductor [221]. The photocatalytic activities of the composite were found to be very high in comparison to that of CdS and TiO_2 used separately.

 TiO_2 coupled with CdS can also be utilized for photocatalytic water splitting due to the more negative conduction band of TiO_2 compared to $E_{H2/H2O}$. So *et al.* prevented the photo-corrosion of CdS with the help of Na_2S during photocatalytic hydrogen generation from water [222]. While the optical absorption of CdS- TiO_2

extends up to 520 nm, this can be utilized for the visible-light induced photocatalytic reactions. Compared to pure CdS and TiO2, a higher rate of hydrogen production was observed for CdS-TiO₂ under visible-light illumination. De et al. proved the improved visible-light activity of CdS-ZnS composite semiconductor for the photocatalytic water splitting [223]. Similar enhancements in the photocatalytic water splitting reactions using CdS-ZnS were also reported by Koca et al. [224] TiO2 coupled with wide band gap semiconductors were found to be highly photocatalytic under UV light. Superior photocatalytic activities of TiO₂-WO₃ and TiO₂-SiC composite semiconductors were observed by Keller and Garin [225]. In the case of TiO₂-SiC composite, the efficient electron injection occurs from the more negative conduction band of SiC to the less negative conduction band of TiO₂. On the other hand, excited electrons transfer from the conduction band of TiO₂ to the less negative conduction band of WO₃ in TiO₂-WO₃ composite. As a result of improved electron-hole separation, these composite semiconductors were more efficient for the photochemical decomposition of methyl ethyl ketone (MEK). Recently, Li et al. synthesized a series of highly visible-light efficient semiconductors by combining N-doped ZnO with WO₃, V₂O₅ and Fe₂O₃ [226]. In these composite semiconductors, visible-light activation was achieved through nitrogen doping and the small band gap semiconductors such as WO₃, V₂O₅ and Fe₂O₃ were responsible for effective electron-hole separation. Coupling of TiO₂ with WO₃ and V₂O₅ were found to be more effective compared to Fe₂O₃ due to carrier recombination on Fe₂O₃. However, these composites were not suitable for hydrogen production due to the less negative position of WO₃ and V₂O₅ conduction bands.

Besides dyes and metal nanoparticles, semiconductor quantum dots (QDs) could also be used for sensitizing TiO₂ photocatalysts, where the QDs absorb light energy and transfer electrons to the conduction band [227]. Recently, extending the visible-

light harvesting with various QDs such as of PbS, InP, CdS, CdTe, CuInS₂, Bi₂S₃ and CdSe attracted a great attention for solar energy conversion [228-235]. A high performance quantum dot sensitized solar cell composed of TiO₂/CuInS₂-QDs/CdS/ZnS photoanode (Figure 13) was reported recently [235]. An efficient way to harvest the entire solar spectrum is by tuning the particle size of QDs [236]. For instance, CdSe quantum dots of particle sizes 2.3, 2.6, 3.0, and 3.7 nm correspond to visible-light absorptions of 557, 543, 520, and 505 nm respectively [237].

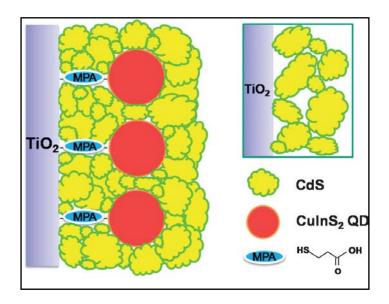


Figure 13. A conceptual schematic of the CuInS₂-QDs/CdS heterostructure on the TiO₂ surface. Reproduced with permission from ref. [235] Copyright 2012 The Royal Society of Chemistry

Additionally, Shockley-Queisser limit of energy conversion efficiency can be overcome by the unique electronic structure of QDs [238]. Moreover, integration of various QDs with different sizes allows energy absorption over a wide range. QDs are excellent sensitizers in solar cells due to their ability to harvest hot electrons and generate multiple carriers [239, 240]. They were also used in combination with dyesensitization and nitrogen doping to enhance the visible-light photocatalytic activity of TiO₂ photocatalysts [241, 242].

An important chalcogenide compound Ag₂S (band gap=1.0 eV) has been investigated as for the visible-light sensitization of TiO₂ nanoparticles for photocatalytic and photovoltaic applications [243, 244]. In addition to semiconductor nanoparticles, carbon quantum dots (CQDs) with excellent broadband light absorption, strong photoluminescence, chemical stability, and nontoxity has been coupled with TiO₂ nanoparticles to improve the visible-light photocatalytic activities [245, 246]. Recently, carrier recombination in QDs sensitized TiO₂ has been reduced by forming a ZnO layer between them [247]. From the computational point of view, the band level arrangement at the heterojunctions between TiO₂ and QDs is a challenging task, even for state-of-the-art methodologies. It has been proposed to use the slab models based on the calculated value of electrostatic energy at the interface as reference for the band-edge positions [248]. This approach was shown to be successful in the case of the ZnO/TiO₂ interface if a proper exact exchange contribution is introduced in the hybrid functional used for performing the calculations.

4.5. Nonstoichiometric TiO₂

Imperfections within the crystal structure significantly affect the phase stability, electronic structure and photocatalytic activity of TiO₂ photocatalysts [8, 115]. TiO₂ samples containing oxygen vacancies were found to exhibit enhanced visible-light absorption, and photocatalytic activities. In the case of TiO₂ containing oxygen vacancies, a partially occupied impurity energy level ~2.0-2.5 eV above the valence band was experimentally observed [249-252]. The additional energy level has also been attributed to the existence of partially occupied Ti³⁺ states, which create energy inter band gap energy levels just below the conduction band [253]. The theoretical modelling of Ti³⁺ centers in reduced TiO₂ is a very delicate issue since they have a strong polaronic character (*i.e.* the electron trapping causes a lattice reorganization around the Ti³⁺ center). The proper position of Ti³⁺ associated states in the band gap of

TiO₂ is not an easy task and must be addresses with electron self-interaction corrected methods (DFT+U or hybrid functionals), since LDA and GGA approaches, which underestimate the band gap value and overestimate the excess electron delocalization, provide the incorrect picture of fully delocalized Ti³⁺ states in resonance with the bottom of the conduction band [254-257]. Heat treatment of TiO₂ under oxygen deficient atmosphere and anionic doping were reported as the key synthesis methods for TiO₂ containing oxygen vacancies.

Oxygen vacancy formation is more pronounced in the case of N doped TiO₂ [142, 258, 259]. Formation of oxygen vacancies and Ti³⁺ ions were experimentally supported by EPR studies and DFT calculations [260]. Formation oxygen vacancies and Ti^{3+} in titanium dioxide calcined under hydrogen atmosphere were reported by previous researchers [115, 261, 262]. Recently, visible-light absorption of TiO₂ has been improved through hydrogenation of TiO₂ [263]. This is a very efficient method in which the mid-gap states above the valence band maximum (Figure 14) due to the hydrogenated, engineered disorders cause band gap narrowing [263]. Though TiO₂ containing oxygen vacancies can absorb visible-light, their quantum efficiencies were low due to increased electron-hole recombination [8, 11, 17]. Identical to oxygen vacancies, oxygen excess defects can also result in new states in the band gap. Etacheri et al. recently synthesized oxygen rich TiO2 through a peroxo-TiO2 route, which demonstrated excellent visible-light photocatalytic activity [8]. In this case, in-situ formation of oxygen creates interstitial oxygen excess defects, which was confirmed from FTIR and XPS studies. These oxygen excess defects bind with lattice oxygen atoms and result in the formation of a substitutional O2 molecule, causing a decrease in lattice parameters.

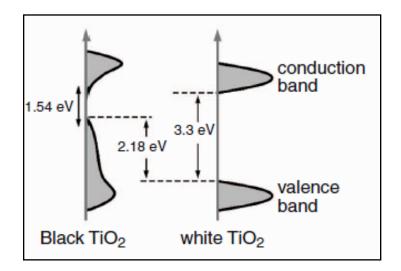
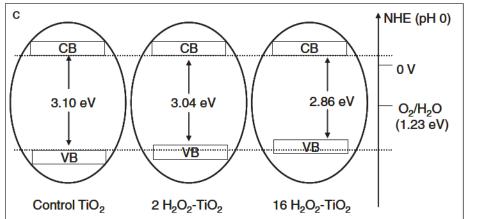


Figure 14. Electronic structure of black hydrogenated TiO₂. Reproduced with permission from ref. [263] Copyright 2011 American Association for the Advancement of Science

Oxygen excess defects also cause band-gap narrowing by valence band shifting (Figure 15), which was confirmed using valence band XPS and photoluminescence (PL) studies. Oxygen rich TiO_2 samples exhibited reduced PL-intensities compared to phase pure anatase TiO_2 due to reduced electron-hole recombination. Oxygen excess defects also act as electron scavengers that increase the lifetime of photo-generated holes and decrease luminescence. Compared to pure anatase TiO_2 and Evonik Degussa P-25, oxygen rich TiO_2 exhibited six-fold and two-fold higher visible-light photocatalytic activities respectively. Only a few studies of interstitial oxygen species are available. These show that an additional neutral oxygen atom prefers to bind to a lattice oxygen atom forming an O–O bond, instead of being stabilized as a charged species in the middle of an interstice [264, 265]. Interestingly, oxygen interstitials are predicted to be good electron traps by GGA+U calculations. The extra electron occupies a σ^* state, which leads to a consistent elongation of the O–O bond from 1.484 to



1.970 Å.

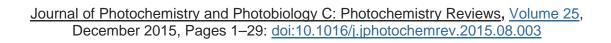
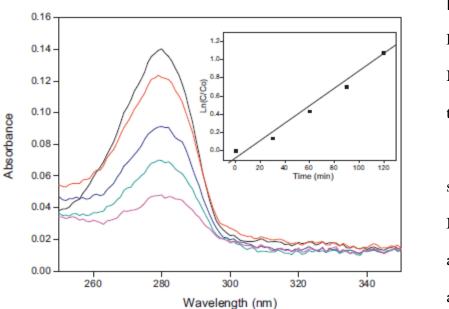


Figure 15. Electronic structure of oxygen rich TiO₂. Reproduced with permission from ref. [8] Copyright 2011 Wiley VCH

4.6. Non-metal doping

4.6.1. Nitrogen doping

Anion doping to enhance the visible-light photocatalytic activity in a semiconductor is a relatively a new method compared to other techniques. Improved visible-light absorption was observed for a variety of anions (N, F, C, S, etc.) doped TiO₂ [142, 266-269]. Non-metal dopants were found to be more efficient compared to most of the metal ions due to the less formation of recombination centers. Asahi *et al.* synthesized a series of anion-doped TiO₂ and also determined the substitutional doping contents of these ions [142]. In contrast to other anion doped TiO₂, the nitrogen-doped compositions has been found to be more effective and extensively investigated [207, 270]. N doped TiO₂ can be synthesized through various physical and chemical methods



[258, 271-275].

Fabrication of

N doped TiO₂

thin film

involved

sputtering under

N₂/Ar gas

atmosphere and

annealing in an

N₂ atmosphere [142, 276, 277]. Sol-gel synthesis of N-doped TiO₂ use 1,3-diaminopropane, and urea as precursor modifier to incorporate nitrogen [278],[10, 279]. N-doped TiO₂ sample calcined at 500 °C was found to be highly effective in the degradation of 4-chlorophenol under solar irradiation (Figure 16). No degradation was recorded for the undoped TiO₂ prepared under similar experimental conditions [278].

Figure 16. Solar photocatalysis of 4-chlorophenol using N doped TiO₂ Reproduced with permission from ref. [278] Copyright 2012 Elsevier Science.

In another study, N-doped TiO₂ powders prepared by treating TiO₂ powder with NH₃ followed by calcinations was reported to be highly active for the decomposition of methylene blue under visible-light irradiation [280]. A mechanochemical method using crystalline TiO₂ and hexamethylenetetramine (HMT) was also reported [281]. Hydrothermal and microwave assisted hydrothermal methods were also very effective for the synthesis of mesoporous TiO₂ containing nitrogen [282, 283].

Electronic structure and type of dopant species of N-doped TiO₂ highly depends on the synthetic method. Several researchers proposed that lattice nitrogen causes the visible-light absorption, while other studies attributed NOx and NHx adsorbed on the surface to band gap narrowing [142, 284]. Thus, a controversy still remains regarding the dopants nature and electronic structure of anion doped TiO₂. Asahi *et al.* illustrated the electronic structure and visible-light absorption of N-doped TiO₂ based on Ti-N bonding [142]. They performed density state calculations and concluded that N-atoms substitute O-atoms of anatase TiO₂, and a consequent mixing of O 2p and N 2p state results in the band gap narrowing. This finding was also supported by the observations of Irie *et al.* [285]. However, a negative contribution of Ti-N bonding towards to band gap narrowing was identified by Diwald *et al.* [286]. However, further detailed

investigations of electronic structure modification mechanism by of $N-TiO_2$ have subsequently been conducted by a number of researchers [258, 285, 287-290].

Di Valentin *et al.* performed a DFT study of N-doped TiO_2 with the hybrid functional B3LYP [260] [269]. Their results showed that substitutional N-doping introduces localized impurity states just above the valence band level, and negligible mixing occurs between N 2p and O 2p states. In the same study it was also shown that N could enter the TiO_2 lattice also in an interstitial position (NO species).

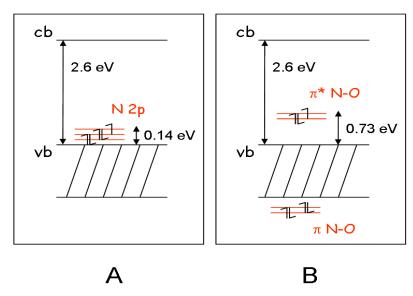


Figure 17. Electronic band structure of (A) substitutional and (B) interstitial N-doped anatase TiO₂. Reproduced with permission from ref. [260] Copyright 2005 American Chemical Society

It is also evident that both conduction and valence band edges are unaffected by the dopants, and visible-absorption is resulted by localized energy levels generated by NO bond [285]. Two bonding energy-levels are positioned below the valence band level, and antibonding orbitals lie 0.73 eV above the valence band. It is also proposed that antibonding NO orbitals act as stepping stone between conduction band and valence band of TiO₂ (Figure 17), [237] and facilitate visible-light absorption [291-293]. Sugihara and co-workers have indicated that nitrogen doping could stabilize oxygen

vacancies, which induce visible-light absorption [258]. This has been fully corroborated by DFT calculations in combination with EPR experiments on N-doped polycrystalline powder samples, showing that the stabilization results from electron transfer between high energy Ti³⁺ states to the low lying N induce impurity states (Figure 18) [294].

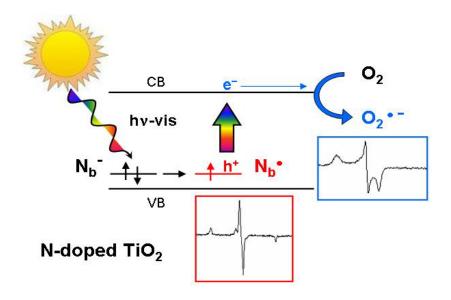


Figure 18. Schematic representation showing electron transfer between high energy Ti³⁺ states to the low lying N induce impurity states. Reproduced with permission from ref. [294] Copyright 2006 American Chemical Society

TiO₂ surface nitrogen doping was also investigated by DFT calculations. Both the rutile (110) and anatase (101) surfaces were considered [295, 296]. Analogous substitutional and interstitial species were identified as in the bulk of TiO₂. The electronic interplay with oxygen vacancies is found to be synergistic; confirming that surface N-doping is expected to cause an enhanced defect concentration. Pillai and coworkers [278] observed an unexpected blue shift in the UV/Vis absorbance of N-TiO₂ samples heat treated at \geq 600 °C. XRD analysis showed that these N doped TiO₂, processed significant amounts of rutile phase. Di Valentin and co-workers [297] had previously explained using theoretical calculations that a blue shift was observed with

N-doped (rutile) because not only the TiO_2 valence band lowered (by 0.4 eV) but the newly introduced N 2p states were also lower in energy than the valence band of pure rutile phase (0.05 eV). This resulted in an overall blue shift due to an effective band gap widening (Figure 19).

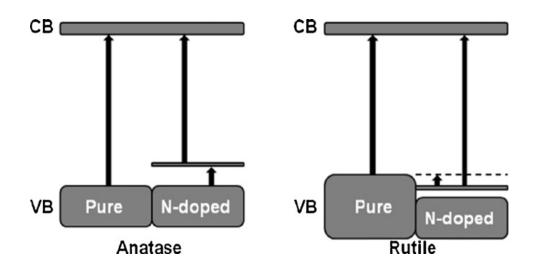


Figure 19. Schematic diagram showing the energy states of pure and N-doped anatase and rutile TiO₂. Reproduced with permission from ref. [278] Copyright 2012 Elsevier Science

4.6.2. Other non-metal doping

Kisch and co-workers for the first time reported daylight-induced photocatalysis using carbon-modified TiO₂ [298]. Many physical and chemical investigations were reported for the synthesis of carbon doped nanoparticles and thin films [19, 299-302]. This narrow band gap TiO₂ showed significantly improved photocatalytic activities up on visible-light irradiation compared to pure anatase TiO₂ and the standard photocatalyst Evonik Degussa P-25. Control of porosity, morphology, and synthesizing hierarchical structures further improved the visible-light photocatalytic activities of C-doped TiO₂ [303-305]. Mechanism of visible-light absorption in C-doped TiO₂ was explained by the formation of Ti³⁺ and oxygen vacancies due to carbon doping [142, 298, 306, 307] Previous researchers performed DFT calculations, and concluded that substitution of

O²⁻ by C-atoms (Ti-C bond formation) resulted in the mixing of O 2p states with C 2p states, and band gap narrowing [306, 308]. However, DFT based calculations of C-doped rutile and anatase TiO₂ clearly indicate that C impurities can be both substitutional and interstitial, depending on the preparation conditions (i.e. oxygen partial pressure). Eventually, both types of species may even coexist since there is a synergistic effect associated to the electron transfer from the oxidized interstitial species to the reduced substitutional one [309].

Another interesting class of visible-light active photocatalyst consist of sulfurdoped TiO₂. Sulfur was detected as hexavalent (S⁶⁺), tetravalent (S⁴⁺), or sulfide (S²⁻), depending on the synthetic method of S-doped TiO₂ [100, 105, 310]. Umebayashi *et al.* thermally oxidized TiS₂ to synthesize anionic S-doped TiO₂, and Ohno *et al.* fabricated cationic S-doped TiO₂ powder through chemical modification of titanium tetraisopropoxide using thiourea [266, 310]. These S-doped materials were found to have notably improved photocatalytic decomposition of 2-propanol and methylene blue under visible-light irradiation. Absorption of visible-light by these photocatalyst are explained by the mixing of O 2p and S 3p states [266, 310]. On the other hand, recent studies explained the band gap narrowing by the formation of S 3p impurity states above the valance band [311, 312]. Formation of S 3p level 0.38 eV above the valence band was identified in the case of cationic S-doped TiO₂ [312]. Though S-doped TiO₂ is a promising visible-light active photocatalyst, incorporation of S in the TiO₂ crystal structure is difficult due to its large ionic radius [313].

It was demonstrated that F-doping is useful for improving the visible-light photocatalytic activity of TiO₂ [314-316]. F-doping was also effective for stabilizing the most reactive (001) facets of anatase TiO₂ [317]. The photocatalytic activity of such F-doped TiO₂ with dominant exposed (001) facets were remarkably higher than

other F-doped TiO₂ nanoparticles [318]. F-doped thin films also showed improved visible-light photocatalytic activities towards the photodegradation of X-3B dye [319]. Iodine doping was also successful for significantly reducing the band gap of anatase TiO₂ photocatalysts [320-323]. Yu *et al.* explained that F-doping cause the reduction of Ti⁴⁺ to Ti³⁺, which resulted in the band-gap narrowing [324]. Li *et al.* confirmed the formation of additional energy levels below the conduction band of F-doped TiO₂ due to oxygen vacancy formation [314].

Iodine is another potential dopant that can induce visible-light absorption by altering the electronic structure of TiO₂ photocatalyst. Cheng et al. synthesized mesoporous bicrystalline network of mesoporous TiO_2 with improved photodegradation of methylene blue under visible-light irradiation [321]. Synthesis, characterization, and electronic structure of multivalent iodine (I⁷⁺/I⁻) doped TiO₂ was reported by Fu et al. [323] It was suggested that the recombination of photogenerated electron-hole pairs is inhibited due to the electron trapping action of the I sites [320]. A maximum absorption edge of 550 nm was experimentally determined for the lattice Idoped TiO₂. Whereas, an extended absorption up to 800 nm was observed for the surface iodine doped TiO₂ [325]. Photocatalytic activities of narrow band gap I-doped bronze phase TiO₂ was nanosheets were also investigated recently [326]. Iodine doped TiO₂ was highly effective for the degradation of dyes, 4-chlorophenol and CO₂ reduction under visible-light irradiation [320, 325, 327]. In the case of I-doped TiO₂, electronic excitation from the I-O-Ti states positioned just above the valence band to the I-O-I levels below the conduction band [325].

Moussab Harb has recently reported the optoelectronic properties of Se-doped TiO₂ using DFT and perturbation theory approach DFPT. A range of selenium doping at various substitutional sites for oxygen or titanium, interstitial sites or at mixed substitutional and

interstitial sites were investigated. Various structures such as $Ti_{(1-2x)}O_2Se_{2x}$ (Se⁴⁺ species), $TiO_{(2-x)}Se_x$ (Se²⁻ species), and $TiO_{(2-x)}Se_{2x}$ (Se²⁻ species) with visible-light optical absorption spectra were identified (Figure 20) [328]. Theoretical predictions were found to be in good agreement with the experimental results. The study of Grey *et al.* that boron doping of TiO_2 lead to partial reduction of Ti^{4+} to Ti^{3+} , which could improve the photocatalytic activity [329]. Compared to other non-metals, boron doping was not investigated in detail. Recently Chen *et al.* reported band gap widening for B-doped TiO_2 , whereas Zhao *et al.* showed a band gap narrowing

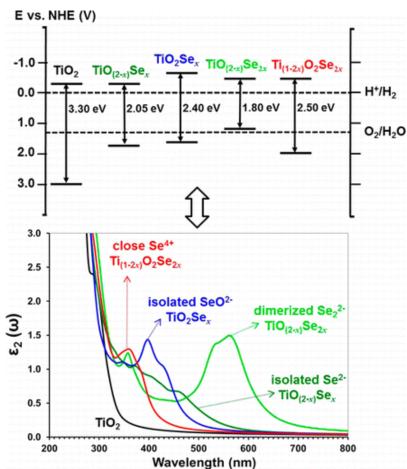


Figure 20. Effect of selenium doping in the visible light activation of anatase TiO2. Reproduced with permission from ref. [328] Copyright 2013 American Chemical Society

It was later demonstrated that proper doping of an optimum B-doping results in significantly higher visible-light absorption and visible-light photocatalytic activities [332]. These B-doped TiO₂ were successfully utilized for the decomposition of methyl orange, methyl tertiary butyl ether, orange II, 4-cholorophenol and nicotinamide adenine dinucleotide (NADH) under visible-light irradiation [330, 332-334]. Based on LDA calculations, the band gap narrowing of boron doped TiO₂ was illustrated by the formation of isolated B 2p impurity levels in the band gap [291]. More refined hybrid density functional results indicate that B enters the TiO₂ lattice in the interstitial sites, forming oxidized borate species and, consequently, reduced Ti³⁺ centers [335].

Several attempts have been reported for the spectroscopic band gap investigation of the anion doped TiO₂. For instance, Etacheri *et al.* [17, 19] performed valence band (VB) XPS to illustrate the consequence of S, N and C doping on the electronic structure of TiO₂, (Figure 21). They identified similar valence band maximum (1.95 eV) for both pure and anion doped TiO₂, which was also identical to the previously reported valence band levels of pure anatase TiO₂ [8, 336, 337]. Additionally, equal width (9.5 eV) of the valence band explained identical mobilities of the photogenerated holes.

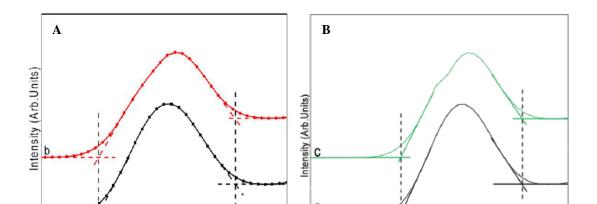


Figure 21. Valence band XPS study of (A) C-doped anatase-brookite heterojunctions (a) Pure TiO₂, (b) C-doped TiO₂. Reproduced with permission from ref. [19] Copyright 2013 American Chemical Society. and (B) S, N- codoped anatase-rutile heterojunctions (a) Pure TiO₂ (b) S, N- codoped TiO₂. Reproduced with permission from ref. [17] Copyright 2012 American Chemical Society

These spectroscopic results clearly ruled out the band gap narrowing due to the mixing of O 2p bands with C 2p, N 2p and S 3p states. Electronic structure of the anion doped TiO₂ highly depends on the electronegativity of dopant atoms. Only poor mixing of C 2p, S 3p and N 2p bands with O 2p bands can be expected due to the low electronegativity of C, S and N atoms (2.55, 2.58 and 3.04 respectively) compared to oxygen (3.44) [291, 292]. Consequently, visible-light absorption of TiO₂ doped with anions such as C, S, and N doped TiO₂ can be illustrated by the electronic excitation from isolated C 2p, S 3p, N 2p, and Π^* N=O states in the band gap. Their findings demonstrated the fact that anion-doping does not actually causing band gap narrowing, and the visible-light absorption resulted from the isolated impurity levels in the band gap (Figure 22).

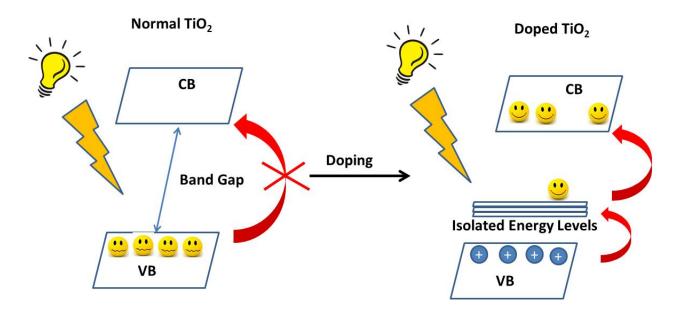


Figure 22. Schematic mechanism of band gap narrowing in anion doped TiO₂.

The computational community has also made an effort to investigate and compare various non-metal dopants [309, 338-343]. Recently, a systematic comparative hybrid DFT study was reported where N, C, B, F dopants are treated at an equal footing (Figure 23) [344]. Clear trends emerged from this study. In particular, B and C are found to be preferentially oxidized by the TiO_2 lattice forming borate or carbonate species and reducing Ti^{4+} lattice sites to Ti^{3+} species. Nitrogen is not inclined to oxidation; even in the interstitial NO form. Fluorine prefers the substitutional (to O) doping mode, which also causes the reduction of lattice Ti^{4+} ions, given the larger atomic number (F > O). All these non-metal dopants are prone to interact with intrinsic defects such as oxygen vacancies and Ti interstitials through long-range internal charge transfer process.

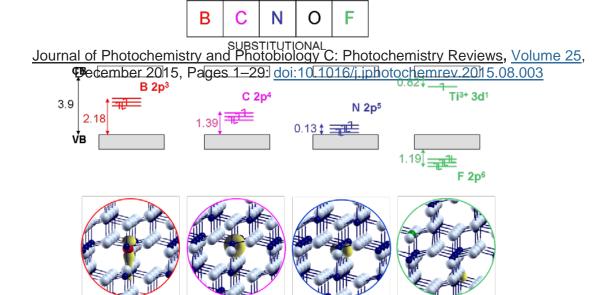


Figure 23 schematic representations of B, C, N and F doping in TiO₂. Reproduced with permission from ref. [344] Copyright 2013 Elsevier Science

4.6.3. Non-metal codoping

Another efficient strategy for increasing the visible-light utilization of non-metal doped TiO_2 was the incorporation of multiple dopants (codoping). For example, (S, N)-codoped anatase TiO_2 exhibited enhanced visible-light photocatalytic performance compared to both S and N-doped TiO_2 [94, 345, 346]. XPS is identified as an effective tool to identify N and S incorporation in TiO_2 photocatalysts [10, 11, 17, 19, 113, 347]. Pillai and co-workers explained that the peak at 402 eV is due to the presence of both NO and chemisorbed nitrogen (Figure 24). Sulfur presents in the TiO_2 show a peak around 169 eV, which was assigned to S^{6+} cation [347].

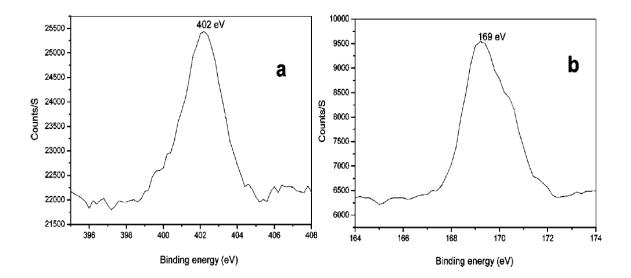


Figure 24. XPS spectra of (a) nitrogen and (b) sulfur in TiO₂ Photocatalysis. Reproduced with permission from ref. [347] Copyright 2009 American Chemical Society.

Modification of TiO₂ precursor by ammonium sulphate and thiourea was found to be the most promising methods for the for the cationic S and anionic N-codoping of TiO₂ nanoparticles [17, 347]. Additionally, Xiang *et al.* recently reported synthesis and improved activity of S, N- codoped (001) facet exposed anatase nanosheets [348]. Superior photocatalytic performance was endorsed to effective band gap narrowing by (S, N)-codoping and exposure of highly reactive (001) facets. Hydrothermal synthesis of B, N-codoped TiO₂ was reported to be highly effective for extending the visible-light absorption and improving visible-light photocatalytic activity. Xu *et al.* developed an organic-free sol-gel method for the fabrication of (C, N)-codoped TiO₂ films, which showed high visible-light photocatalytic activities toward the photodegradation of stearic acid [349]. (C, N)-codoped TiO₂ with special morphologies such as nanotubes and nanorods have been also reported previously. These visible-light active photocatalysts were superior to Evonik Degussa P-25 for the photodegradation of Rhodamine-B [350]. Macroporous TiO₂ microspheres codoped with C and F were highly efficient for the visible-light photocatalytic degradation of styrene [351].

Notably improved photocatalytic performance of mesoporous hierarchical TiO₂ containing C and S dopants was also reported recently [352]. First principle electronic structure calculation and XPS studies of (B, N), (B, I), (B, F) and (C, N)-codoped TiO₂ identified a synergetic effect between individual anions are accountable for the improved visible-light absorption [353, 354]. Visible-light absorption up to 700 nm was observed in the case of (C, N)-codoped TiO₂. Highly visible-light active B, N codoped red anatase TiO₂ microspheres with a band gap of 1.94 eV on the surface and 3.22 eV in the core has been reported recently [355]. The synthesis method involved pre-doping of TiO₂ with boron to weaken the Ti-O bonding, and thereby improving the solubility of the second dopant nitrogen. In this case, visible-light absorption has been extended up to 700 nm (Figure 25), and colour changed from white to red, which is completely different from the yellow colour and small visible-light absorption of N-doped TiO₂. Substitutional nitrogen doping in this case was also demonstrated using Raman spectroscopy.

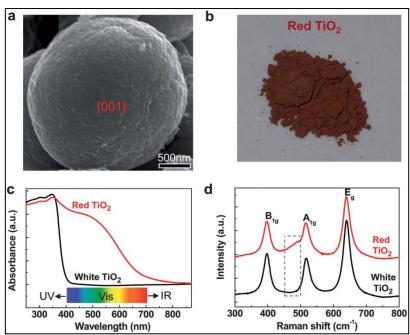


Figure 25. (a) SEM image of a red TiO₂ microspheres; (b) optical photograph of the prepared red TiO₂ sample; (c) and (d) UV-visible absorption and Raman spectra of the white and red TiO₂. Reproduced with permission from ref. [355] Copyright 2012 The Royal Society of Chemistry

The principles at the basis of the synergistic effect of non-metal codoping for visible-light photocatalysis were unravelled again by means of DFT calculations [356-360]. The most efficient pairs, such as N-F codopants, essentially present and electron donor (F) and an electron acceptor (N) which interact through internal long-range charge transfers, in analogy with what observed for non-metal impurities with oxygen vacancies. A donor species is an excellent substituent of the oxygen vacancy; therefore it has the beneficial effect of largely reducing the sample defectivity, commonly associated for example with N-doping. Thus, the role of one dopant (e.g. N) is to induce the visible-light absorption properties, whereas the role of the second dopant (e.g. F) is to compensate the overall electron counting, which is an efficient way to avoid the undesired formation of lattice defects. The photocatalytic activity can largely benefit from these effects since the electron/hole recombination rate is found to be directly proportional with the presence of lattice defects. Hamilton et al. [361] employed photo electrochemical measurements to examine the mechanism of visible light photocatalysis. The N,F doped TiO₂ did not provide any significant photocurrent response in presence of visible light at fixed potential under monochromatic irradiation, as compared to band gap irradiation (Figure 26). Addition of KI and hydroquinone as 'hole acceptors' showed slight increases in the photocurrent. KO₂ (superoxide source) produced enhancement of photocurrent under visible light. This improvement in the photocurrent is explained as the oxidation of superoxide radical to singlet oxygen by the mid-gap level formed by N doping.

The F-doping induces the creation of shallow Ti³⁺ donor levels slightly below the conduction band. Oxygen vacancies transfer electrons to re-populate N states. The conduction band electrons can then move to the oxygen vacancies. Therefore a cycle

of excited electrons occurred starting at the N mid-gap state, to conduction band and then to Ti³⁺ or oxygen vacancies with subsequent re-population of the empty nitrogen states (Figure 27). The occurrence of visible light activity in this example is explained as mainly due to the reduction reaction involving conduction band electrons with molecular oxygen.

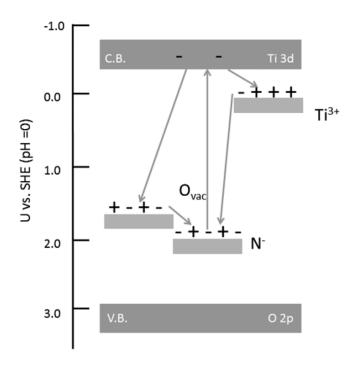


Figure 26. Mechanism of electron transfer from either Ti³⁺ or oxygen vacancies in N-F doped TiO₂ explained using photo-electrochemical studies. Reproduced with permission from ref. [361] Copyright 2014 American Chemical Society

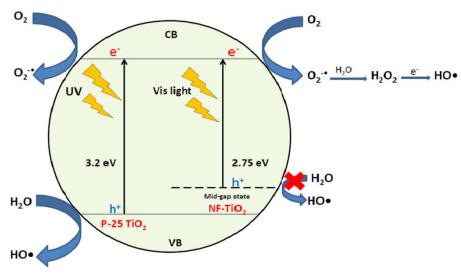


Figure 27. Role of various reactive oxidation species during the photocatalysis process of N-F doped TiO₂. Reproduced with permission from ref. [362] Copyright 2014 Elsevier Science

Zhao *et al.* [362] conducted TiO_2 photocatalysis of 6-hydroxymethyl uracil (a model Cyanobacteria toxin or cynotoxin) using various non-metal doped TiO_2 materials. It was found that N-F- TiO_2 was the most active photocatalyst, while P-F- TiO_2 showed marginal activity and S- TiO_2 was fully inactive. In order to understand the mechanism of action, they also have conducted the photocatalysis in presence of a number of scavengers for $O_2 \bullet^-$, 1O_2 , HO• and h_{vb}^+ . These investigation showed that $O_2 \bullet^-$, is the leading ROS (reactive oxidation species) employed for the photocatalytic destruction of 6-hydroxymethyl uracil (Figure 21).

4.6.4 Metal non-metal codoping

Co-alloying of anion doped TiO₂ with metal ions is another effective method for improving the visible-light photocatalytic activity of TiO₂ [363-366]. The benefits of co-alloying have been validated in numerous compositions including N/Fe³⁺, N/V⁵⁺, N/Sn²⁺, N/Ta²⁺, N/Ni³⁺, N/Cr³⁺, N/W⁵⁺, N/Ce³⁺, N/La³⁺, N/Sm³⁺ and C/V⁵⁺ [367-377]. Performances of these co-doped TiO₂ were significantly higher than those containing single dopants. For Instance, visible-light photocatalytic activity of Nb-coalloyed N-doped anatase TiO₂ was 7-fold higher in contrast to the undoped phase [363]. (Ga, N) codoped anatase TiO₂ was reported to be highly visible-light active for the water decomposition to hydrogen [378]. Increased oxygen vacancy formation and the band gap realignment leading by the synergetic effect of Ga and N-ions were responsible for the enhancement of photocatalytic activity. For increasing the visible-light photocatalytic activities, Li *et al.* successfully co-alloyed Mo with C-doped TiO₂ through a hydrothermal method [379]. This resulted in the formation of narrow band

gap TiO₂ with lattice Mo⁶⁺ (Ti-site substitution) and surface adsorbed carbon impurities. In this case, synergetic effect of the individual ions resulted in the enhanced photocatalytic activity. In addition to the visible-light absorption, Mo and C dopants also improved the photogenerated electron-hole separation. A one step solution combustion method was developed by Thind *et al.* for the synthesis of mesoporous (N, W) codoped TiO₂, which exhibited superior decomposition of Rhodamine-B under visible and UV-light irradiation [380].

Several studies on the metal/non-metal codoping of TiO₂ are present in the literature [381-384]. The underlying mechanisms for the enhanced photocatalytic activity of the codoped systems are analogous to those described for non-metal codoping. The presence of one dopant is found to favour the introduction of the second in the TiO₂ lattice. Besides enhancing the visible-light absorption, due to the different chemical nature, the two codopants are found to facilitate the photogenerated electronhole separation, with beneficial consequences on the measured photocurrent and observed photocatalytic activity.

4.6.5. Non-metal doped heterojunctions

Increased recombination of photogenerated electron-hole pairs due to inter band gap impurity energy levels is the main drawback of anion doped TiO₂. Theoretical studies of these narrow band gap TiO₂ using DFT calculations proved that anion doping cause a substantial lowering of energy required for oxygen vacancy formation. Photoelectrochemical studies of N doped anatase TiO₂ demonstrated the existence of supplementary energy levels located 1.3 eV below the conduction band level [385]. These additional energy levels act as recombination sites for the photogenerated electron-hole pairs. Increased dopant concentration also promotes carrier recombination through band gap narrowing. Thus visible-light photocatalytic activity

of anion doped TiO₂ is limited due to the increased rate of electron-hole recombination. Consequently, coupling of anion doped TiO₂ with electron-hole separating agents (metal nanoparticles, quantum dots, semiconductor nanoparticles etc.) are necessary to attain high photocatalytic activity. Improved photocatalytic performance of biphasic TiO₂, for example Evonik Degussa P-25 (70 % anatase + 30 % rutile) under UV-light irradiation has been reported earlier. Efficient electron transfer from anatase to rutile was found to be responsible for the enhanced activities of these mixed phase photocatalysts [67, 386]. Similar approaches have also been implemented for improving the performance of several anion doped TiO₂ polymorphs. A microwave hydrothermal method for the synthesis of high surface area N-doped TiO₂ containing anatase and rutile nanoparticles has been reported by Zhang *et al.*[387] These biphasic narrow band gap TiO₂ outperformed the standard commercial photocatalyst Evonik Degussa P-25 towards the decomposition of NO_x gas.

In addition, Etacheri *et al.* recently reported novel synthetic methods and superior visible-light induced photocatalytic performances of N-doped/S, N-codoped anatase-rutile heterojunctions and C-doped anatase-brookite heterojunctions [11, 17, 19]. These visible-light active TiO₂ nanoheterojunctions exhibited notably higher photocatalytic activities compared to pure anatase phase, single-phase anion doped TiO₂, and the commercial biphasic standard photocatalyst Evonik Degussa P-25 [11, 17]. Improved separation of electrons and holes at the anatase/rutile and anatase/brookite interface due to anatase to rutile and brookite to anatase electron transfer was demonstrated as the key reason for their very high photocatalytic activities (Figure 28). Moreover, various anion doped anatase TiO₂ coupled with Ag and Au nanoparticles also exhibited superior visible-light photocatalytic activities compared to their single-phase counterparts [388-391]. These studies demonstrate the necessity of

combining anion-doped TiO₂ with electron-hole separating agents for attaining the best visible-light photocatalytic activity. As mentioned in Section 4.4, the band alignment of different materials or of different phases of the same material, as in this case (rutile *vs.* anatase TiO₂), is a critical aspect and a challenging task, even for contemporary methodologies. Recently, a combined experimental and theoretical study has demonstrated that anatase possesses a higher electron affinity or work function with respect to rutile, resulting in a staggered band alignment of about 0.4 eV. The two polymorphs were modelled with QM/MM finite clusters for which the absolute values of ionization potentials and electron affinities can be obtained by computing charge states [392].

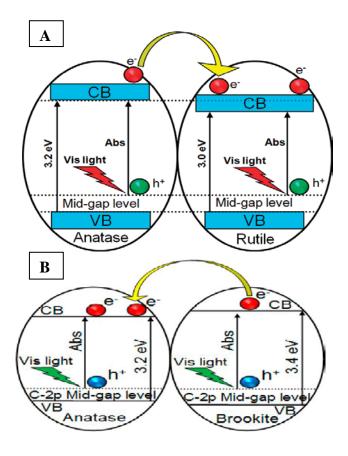


Figure 28. Electron transfer mechanism in (A) S, N- codoped anatase-rutile heterojunctions Reproduced with permission from ref. [17] Copyright 2012 American Chemical Society. (B) C-doped anatase-brookite heterojunctions. Reproduced with permission from ref. [19] Copyright 2013 American Chemical Society

5. Graphene, carbon nanotube, g-C₃N₄ and perovskite modified TiO₂

Recently, coupling between TiO₂ and graphene have attracted much attention for considerable improvement in the photocatalytic performance [393-397]. Strong absorption of visible-light, unique 2-D morphology, and high electronic conductivity of graphene were found to be responsible for the photocatalytic activity enhancement. Graphene is an excellent electronic conductor that scavenge photo-excited electrons on TiO₂ surface [398, 399]. In addition, large surface area and 2-D planar structure of graphene enable the anchoring of impurities and TiO₂ (Figure 29) for increasing the photocatalytic activity. A number of methods have been presented for the synthesis of graphene-TiO₂ composites with improved visible-light photocatalytic performance. Most of these synthetic methods involve photocatalytic, chemical and hydrothermal reduction of a suspension or thin films of graphene oxide (GO) and TiO₂ [393, 398, 400-407]. These TiO₂-RGO hybrids exhibited excellent photocatalytic activities towards the degradation of methylene blue, benzene, *E. coli* bacteria, and water oxidation. In the case of photocatalytic water splitting, RGO also act as an excellent co-catalyst due to its high surface area and superior electron mobility.

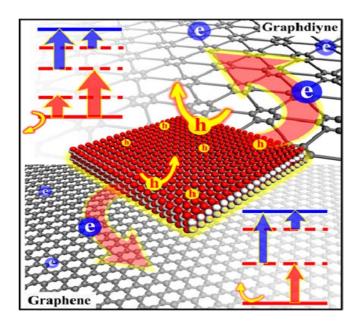


Figure 29. Photoinduced electron transfer mechanism in graphene and graphdiyne modified TiO₂. Reproduced with permission from ref. [405] Copyright 2013 American Chemical Society

Recently, Kamat *et al.* verified the electron scavenging activity in a TiO₂-graphene hybrid photocatalyst [408]. Composites consists of TiO₂ nanorods and (001) face exposed nanoparticles/nanosheets on large graphene sheets were reported to exhibit enhanced photocatalytic H₂-production activity [409-411]. Graphene-TiO₂ composite coupled with Ag nanoparticles, which combine the plasmon sensitization and excellent electrical properties of graphene has been reported as an excellent photocatalyst under visible-light irradiation [395].

In another recent investigation to understand the photocatalytic mechanism of visible light active ZnO-graphene composites, Kavitha *et al* used reagents such as a radical scavenger t-BuOH and a hole scavenger EDTA-2Na [412]. The addition of radical scavenger t-BuOH did not provide any significant changes in the photo-degradation properties, while the incorporation of EDTA-2Na significantly reduced the photo-degradation properties. This study has proved that the photo-generated holes are the major ROS responsible for the photo-

degradation properties. Fluorescent quenching occurred in the zinc oxide–graphene composites showed photo-induced electron transfer (Figure 30),. These charge transfer processes could significantly improve the photocatalytic activity by reducing the recombination of electron-hole pairs. It has been concluded that the appropriate absorption range, effective electron-hole charge separation and high surface area make the ZnO–graphene hybrids a better photocatalyst under UV and visible light [412].

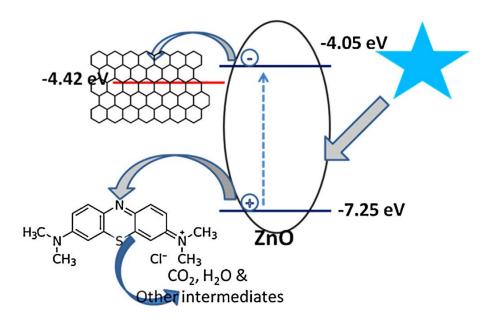


Figure 30. Mechanism of photocatalytic degradation using ZnO-Graphene hybrid. Reproduced with permission from ref. [412] Copyright 2015 Elsevier Science

In this photocatalyst, Ag nanoparticles enhance the visible-light absorption, and graphene effectively separate photogenerated electron-hole pairs, which significantly improve the photocatalytic performance. Highly visible-light active hybrid semiconductor heterostructure of TiO₂/Bi₂O₃/graphene has been also reported previously [413]. Formation of Ti-C chemical bonds in TiO₂/graphene composites were identified to be enhancing the efficiency of photo-induced interfacial electron transfer [414]. Photocatalytic performances of these chemically bonded composites are exceptional compared to pure TiO₂ and the physically mixed samples with no chemical

bonds. Multi-walled carbon nanotube (MWCNT) is a promising alternative to graphene for the visible-light activation of TiO₂ and for electron scavenging [415].

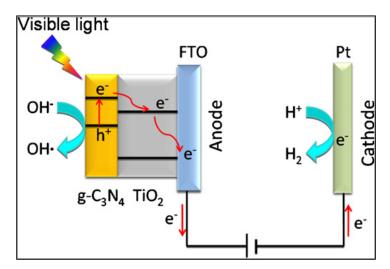


Figure 31. Mechanism of charge separation and transfer between g-C₃N₄ and TiO₂ nanorod arrays under visible-light irradiation. Reproduced with permission from ref. [416] Copyright 2012 Elsevier Science

As a result of the narrow band gap (2.75 eV) graphitic carbon nitride (g-C₃N₄) has attracted a considerable interest in the field of visible-light induced photocatalysis [417-421]. Due to strong covalent bonds between nitrogen and carbon atoms, g-C₃N₄ is considered as the most stable carbon nitride under acidic and basic conditions [416]. It was noted that nitrogen doping using urea precursor result in the formation of some carbon nitride polymers on the TiO₂ surface [422, 423]. Subsequently, Wang *et al.* reported the powerful visible-light water splitting activity of g-C₃N₄ with a conjugative polymeric structure [424]. Visible-light photocatalytic activity of TiO₂ was extensively improved after modification with g-C₃N₄ [416, 420, 425, 426]. Yan *et al.* found that coupling of TiO₂ with g-C₃N₄ remarkably improved the visible-light water splitting performance by transferring photoexcited electrons from g-C₃N₄ to TiO₂ [427]. In the case of TiO₂- g-C₃N₄ hybrids, interfacial electron transfer is facilitated by the higher conduction band level of g-C₃N₄ [424]. It is proposed that in addition to sensitization,

g-C₃N₄ is also capable of separating photogenerated charge carriers (Figure 31),[416] which is analogous to other carbonaceous materials such as carbon nanotubes,[428] and graphene [429-431].

Organo-lead halide perovskites possessing narrow band gap, improved stability in dry air, high carrier mobility, and great absorption coefficient were recently reported as efficient visible-light harvesters in heterojunction solar cells [432-437]. Use of CH₃NH₃PbI₃ as sensitizer in photo-electrochemical cells with liquid electrolyte has been reported previously [438-440]. However, dissolution of the sensitizer resulted in rapid performance decay, which was later solved by using a solid-state electrolyte [441]. A power conversion efficiency (PCE) of 8.5% has been demonstrated recently for a solid-state solar cell containing CsSnI₃ perovskite hole conductor and N719 as sensitizer [442]. Extremely high room temperature hole mobility ($\mu h = 5585 \text{ cm}^2 \text{V}^{-1} \text{S}^{-1}$ ¹) and narrow band gap (1.3 eV) of CsSnI₃ makes it an ideal sensitizer. Further increase in the power conversion efficiency (n) and photocurrent density (J_{SC}) was achieved by F and SnF₂ doping of CsSnI₃ [442]. A heterojunction solar cell composed of CH₃NH₃PbI₃ perovskite (which act as absorber and hole-conductor) and (001) facet exposed TiO₂ nanosheets was also reported recently (Figure 32) [443]. A remarkably high photovoltaic performance was observed for this heterojunction cell compared to the previous reports.

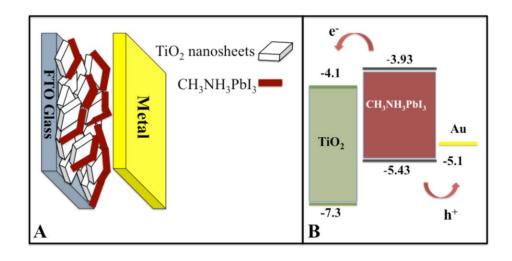


Figure 32. (A) Device structure and (B) Energy level diagram of the CH₃NH₃PbI₃/TiO₂ heterojunction solar cell. Reproduced with permission from ref. [443] Copyright 2012 American Chemical Society

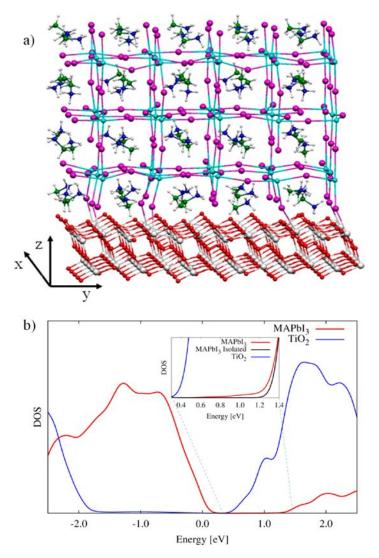


Figure 33. (a) Optimized structure of the simulated TiO₂/MAPbI₃ interface along with reference axes. (b) Calculated DOS including spin—orbit coupling for the TiO₂/MAPbI₃interface, decomposed into the contributions of MAPbI₃ (red) and TiO₂ (blue). The inset shows the bottom of the interacting perovskite DOS, compared with the noninteracting DOS at the same geometry. Reproduced with permission from ref. [444] Copyright 2014 American Chemical Society

A number of computational studies, based on standard DFT but also on the more sophisticated GW approach (see Section 3), mostly by F. De Angelis *et al.*, have investigated perovskite-based solar cells (Figure 33), with particular attention to the oxide/perovskite interface [444-

452]. These works have been able to reveal fundamental aspects of the device's operational mechanism.

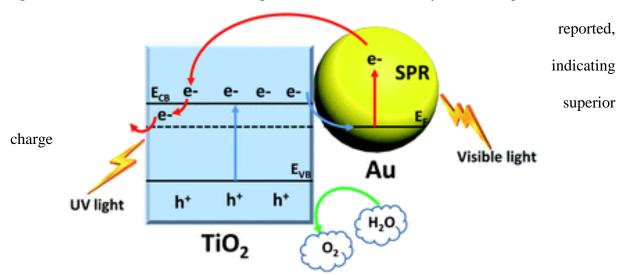
6. Recent developments in visible light active TiO₂

Noteworthy advances have been recently made on the application of TiO₂ photocatalysts for visible-light induced water splitting, degradation of environmental pollutants, water/air purification and antibacterial applications. While visible-light activation of TiO₂ are developed through one of the modification or band-gap engineering discussed above, charge separation is another key factor need to be addressed for the efficient use of TiO₂ for these applications [453]. Recent developments in the area of visible-light induced water splitting involve the use of a variety of cocatalysts and electron-hole separating agents. Since the Fermi level of noble metal are lower than that of TiO₂ photocatalyst, photogenerated electrons are entrapped by the metal nanoparticles anchored on the semiconductor surface. Platinum has been widely used as the cocatalysts over many other metal oxides and up until now the highest H₂ generation performance are from Pt-loaded photocatalysts [454-457]. Recently, Iwase et al. reported excellent H₂ production using Au-modified TiO₂ [458]. This mainly resulted due to creation of active sites for water splitting and reduced charge recombination. Another major advantage of these Au cocatalysts is the negligible back reaction (recombination of H₂ and O₂ to form H₂O) compared to Pt cocatalysts. Wu et al. investigated the photocatalytic performance of Rh loaded TiO₂, and found enhanced rate of H₂ production [459]. They explained this unusual enhancement by the Schottky barrier formed at the TiO₂-Rh interface that acts as an efficient electron trap, preventing electron-hole recombination.

Type of electronic interactions between metals and semiconductors are used for explaining the effect of various noble metal cocatalysts [460]. It was suggested that smaller Schottky barrier height at the metal/semiconductor interface is beneficial for improved electron flow and photocatalytic activity for water splitting [461]. When Au/Pd bimetallic

cocatalysts are loaded on the TiO₂ surface, significant H₂ production efficiency from aqueous ethanol solutions was observed due to selective donation of electrons to the protons [462]. Synergistic effect in the visible-light photocatalytic activity of TiO₂ was observed by Borgarello et al. when both RuO₂ and Pt nanoparticles are deposited on the surface [140]. They proposed that Schottky barrier is formed by RuO₂, while Pt provides ohmic contact acting as electron trap, while holes are trapped by RuO₂. Moreover, Teramura et al. reported that uniform dispersion of RuO₂ nanoparticles on TiO₂ is essential for obtaining improved H₂ and O₂ evolution [463]. Tada et al. developed a three component CdS-Au-TiO₂ photocatalyst, which exhibited water splitting photocatalytic activity exceeding most of the single and two component systems [464]. Further investigation of this composition was carried out by Park et al., and found that direct contact between CdS and TiO₂ are required for vectorial electron transfer and highest photocatalytic activity [465]. Similar performance increase was also observed in the case of MWCNT-TiO₂ and Bi₂S₃-TiO₂ systems [466, 467].

Recently, branched TiO₂ nanorod arrays modified with plasmonic Au nanoparticles are demonstrated as highly efficient for photoelectrochemical water splitting under visible-light illumination [468]. The obtained photocurrent and efficiency was the highest value ever



separation and transportation efficiencies. The high water splitting performance was attributed to the plasmonic effect of Au nanoparticles, which increases visible-light absorption and improve charge separation/ carrier mobility (Figure 34). Similar approach was also employed in the case of Au-nanoparticle modified TiO₂ aerogel [469]. The magnitudes of photocatalytic activity improvement in this case prove that a three-phase boundary is beneficial for excited surface plasmon to charge-carrier conversion (Figure 35).

Figure 34. Mechanism of visible-light driven photoelectrochemical water splitting on Au nanoparticles modified dendritic TiO₂ nanorod arrays. Reproduced with permission from ref. [468] Copyright 2013 Royal Society of Chemistry

Biphasic TiO₂-Fe₂O₃ photocatalysts are also modified with plasmonic metal nanoparticles to induce visible-light activated photocatalytic water splitting [470]. In this case, a photocurrent 20 times higher than pure Fe₂O₃ was observed using an optimized ratio of plasmonic TiO₂-Fe₂O₃/Ag composition. Absorption of incident photons and charge carrier separation was enhanced due to broadband absorption and strong electric field of the composite. Improved photoelectrochemical water splitting was also reported using Fe-doped TiO₂ nanorod arrays [471]. This work demonstrated Fe-doping as the most effective method to improve the photocatalytic activity of TiO₂. Efficiency measurements reveal that Fe-doping improve UV/Vis absorption by creating additional energy levels near conduction band and increase the carrier density, leading to effective carrier separation. S-doped TiO₂ nanotube arrays are recently reported as a highly active photocatalyst for photoelectrochemical water splitting [472]. Three component CdS-TiO₂/metallosilicates were also reported as effective for visible-light induced photocatalytic water splitting [473].

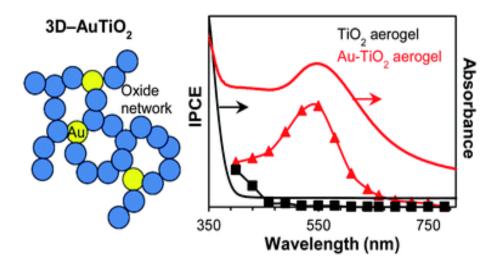


Figure 35. Plasmonic enhancement of the visible light water splitting with Au-TiO₂ composite aerogel. Reproduced with permission from ref. [469] Copyright 2013 Royal Society of Chemistry

TiO₂ photocatalysts are recently proved as very effective towards visible-light induced decomposition of a number of organic and inorganic pollutants [474-482]. Recent developments in this area include the synthesis of novel TiO₂ compositions containing anions, cations, metal oxides and carbonaceous materials. Cavalcante et al. synthesized B-doped TiO₂ through a boric acid modified sol-gel method, and tested for the sunlight driven degradation of metoprolol [474]. They found a significant increase in the photocatalytic activity (48 to 70 % by doping 5 %) due to B-doping. 5% was identified as the optimum B-loading, which resulted in high surface area and mesoporous structure. Boron was introduced into the crystal structure as B-O-Ti, which causes Ti³⁺ formation due to charge compensation. Photocatalysis play an important role in water purification. Zhang et al. reported humic acid removal from water through photocatalytic decomposition using hybrid Fe₂O₃/TiO₂ nanowires [475]. These membranes also exhibited antifouling property up on sunlight irradiation. Fe₂O₃ played an important role in the biphasic catalyst by improving humic acid adsorption, increasing electron-hole separation by interfacial charge transfer, and by absorbing visible light. Under UV-light irradiation, electron-hole pairs are generated on both TiO₂ and Fe₂O₃ (Figure 36a). Water oxidation by holes produces OH radicals, which in turn decompose humic acid molecules. Under visible-light irradiation, Fe₂O₃ absorbs visible light and transfer conduction band electrons formed to the electron trapping sites of anatase TiO₂ (Figure 36b).

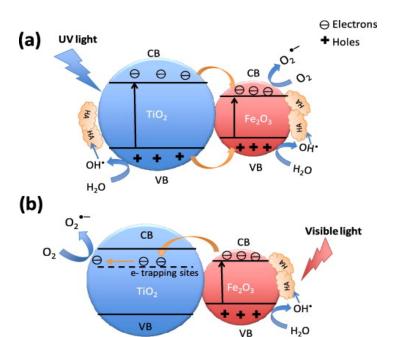


Figure 36. Proposed mechanism for the photocatalytic degradation of humic acid on Fe₂O₃/TiO₂ hybrid nanowires under UV and visible light irradiation. Reproduced with permission from ref. [475]. Copyright 2015 Elsevier Science

Nanocomposite formation between TiO2 and clay is a recently reported method for the photocatalytic removal of phenol and methylene blue from water [476]. In this method, photoresponse of the final composite was shifted from UV to the visible light range. Their kinetic study proved that TiO₂-clay nanocomposites are efficient for phenol and methylene blue removal from water under UV and visible light.

An efficient sonophotocatalytic degradation of reactive blue 19 (RB 19) using sulfurdoped TiO₂ nanoparticles was reported recently [477]. In this method, coupling of ultrasound and photocatalysis improved dye degradation through synergistic effect, which increased the amount of reactive radicals OH and H₂O₂. It is also proposed that ultrasound increases the mass transport between the solution phase and catalyst surface, and de-agglomeration of particles increase the surface area of the catalyst. Jiang et al. recently reported a novel ternary photocatalyst composed of TiO₂-In₂O₃ nanocrystals decorated with g-C₃N₄ for dye degradation and H₂ evolution [481]. These ternary composites exhibited the highest RhB degradation rate, which is 6.6 times higher than that of g-C₃N₄. H₂-generation rate was 48 times of the pure g-C₃N₄. They attributed the enhanced photocatalytic activity to efficient interfacial transfer of photogenerated electrons and holes among TiO2, In2O3 and g-C3N4 (Figure 37).

g-C₃N

RhB

degradation

In₂O

degradation

Figure 37. Possible photocatalytic mechanism of the TiO₂-In₂O₃ -g-C₃N₄ ternary hubrid composite. Reproduced with permission from ref. [481]. Copyright 2015 Elsevier Science Other recent developments in the area of visible-light induced environmental cleaning involve the use of GO-TiO₂ composites for Microcystin-LA removal [479], N-doped TiO₂ on glass spheres for Eriochrome Black-T decomposition [480], and CdO/TiO₂ coupled semiconductor for Reactive Orange degradation [478]. Superior decomposition of air pollutants by visiblelight active TiO₂ photocatalysts have been lately reported by several researchers [483-487]. Bacterial killing under visible-light irradiation is one of the most versatile applications of TiO₂ photocatalysis. Various strategies are recently developed for the visible-light activation of TiO₂ for visible-light induced bacterial killing. Lin et al. reported the synthesis of Se/Te-TiO₂ nanorods with dominant (001) facets with high visible-light photocatalytic activity [488]. In this case, highly active (001) facets exhibited significantly higher antibacterial activity than Degussa P25 when activated under visible-light. A sol-gel method is recently demonstrated for the synthesis of Ni^{2+} doped TiO_2 with superior antibacterial activity towards Staphylococcus aureus, Escherichia coli, Bacillus subtilis, and Salmonella abony under visible-light irradiation [489, 490]. Surprisingly, antibacterial performances of this Ni²⁺-doped TiO₂ are superior to N-doped TiO₂ under similar experimental conditions.

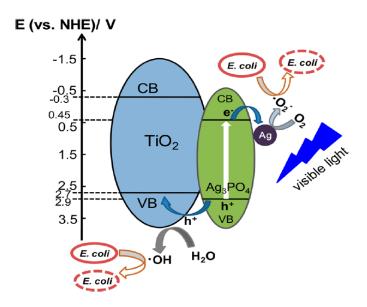


Figure 38. Visible-light induced antibacterial activity Ag₃PO₄/TiO₂/Fe₃O₄ heterostructure toward *E. Coli*. Reproduced with permission from ref. [491]. Copyright 2014 American Chemical Society

Heterojunctions with carbonaceous materials, metal nanoparticles, metal oxides and phosphates are reported as effective for improving the visible-light induced antibacterial activity of TiO₂ [491-496]. Akhavan et al. incorporated CNTs with TiO₂ thin films for the visible light photoinactivation of *Escherichia coli* bacteria [492]. Post annealing of this film resulted in the formation of Ti-C and Ti-O-C bonds. Bacterial inactivation in the dark was also observed for films containing higher CNT loading. Improved visible-light was assigned to the charge transfer between CNTs and TiO₂ through the carbonaceous bonds formed. Xu et al. recently reported the synthesis of magnetically separable Ag₃PO₄/TiO₂/Fe₃O₄ heterostructure for photoinactivation of bacteria [491]. This three component photocatalyst exhibited excellent photocatalytic activity, and photogenerated oxidants (•OH and •O₂⁻) formed caused a strong considerable morphological changes in the cells and bactericidal effects toward *Escherichia coli*. Visible-light activation was caused by narrow band gap Ag₃PO₄, and effective transfer of photogenerated holes to the valence band of TiO₂ (Figure 38). Moreover, Etacheri et al. reported outstanding antibacterial performance of C-doped

TiO₂ heterojunctions composed of nanosized anatase and brookite nanoparticles. A microwave synthetic method was used for the rapid synthesis of these nanoheterojunctions, and 90% bacterial killing occurred within 3 h visible-light irradiation. High visible-light induced photocatalytic activity was attributed to the efficient transfer of photogenerated electrons from the conduction band of brookite to that of anatase (Figure 39), which facilitate the formation of reactive oxygen species and bacterial killing.

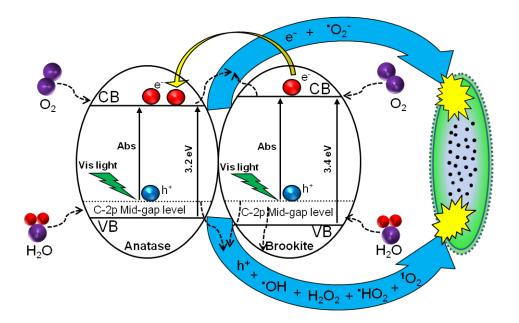


Figure 39. Mechanism of visible-light induced photocatalytic bacterial killing using carbon doped anatase-brookite heterojunctions. Reproduced with permission from ref. [497].

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7. Strategies to select dopants and future recommendations for an improved electron-

hole separation

In the last decades great attention has been paid to the synthesis of transition-metal ion doped TiO₂ possessing high photocatalytic activities to satisfy the requirements for practical applications. However, until now many questions are still open considering

both the mechanism by which metal doping improves the photocatalytic activity as well as the determination of the optimal doping ratio. It is assumed that at low doping concentration the doping ions traps electron-hole pairs thus reducing the recombination rate, while at a higher doping ratio the formation of recombination centers occurs [40]. Consequently, for every transition metal doped TiO_2 there is an optimal dopant concentration. Bloh *et al.* developed a theoretical model, which describes the dependency of the photonic efficiency on the doping ratio and which can thus be applied for the determination of optimal transition metal-ion ratio [498]. The idea behind this model is that the direct cationic neighbourhood of two dopant metal cations can be considered as recombination center, while more distant dopants can be ignored, since they induce a lower recombination probability. With increasing doping ratio, both the probability for the formation of the clusters and the amount of the doping atoms increases. The cluster ratio r_c , i.e., the product of the doping ratio and the cluster probability, depends quadratically on the doping ratio r_d and can be describe by the following equation:

$$r_{\rm c} = n r_{\rm d}^2$$

Where, n corresponds to the number of the neighbouring cations (n=12 for TiO₂ or ZnO (wurzite)). It is assumed that the photonic efficiency increases linearly with the doping ratio due to the formation of the charge carrier trapping centers, while it concurrently decreases quadratically with the doping ratio due to the formation of recombination centers. The relation between doping ratio and photonic efficiency is shown in Figure 40. Moreover, the experimentally determined data correlate very well with developed theoretical model. However, both the position and the height of the maximum can vary depending on the nature of dopants, ionic radius, number of the cationic neighbours, and the separation among the cations.

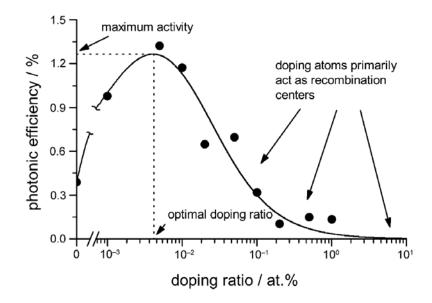


Figure 40. The photocatalytic activity as a function of the doping ratio. Reproduced with permission from ref. [498] Copyright 2013 Wiley VCH

The drawback of the above-described model is that it does not consider the dependency between particle size, morphology, and optimum dopant ratio. Zhang *et al.* suggested a theory indicating a correlation between the optimal Fe³⁺-doping ratio and the particle size of TiO₂, though, they have not developed a model to describe this phenomenon [499]. In a similar study, Bloh *et al.* presented another model that explaining the relationship between dopant content, particle size and photocatalytic activity [500]. This model assumed small dopant concentration, formation of recombination centers, and presence of at least one dopant atom per particle to achieve a doping action. This model (Figure 41) includes the correlation between particle size and dopant content, defining regions with too many empty particles or too many cluster occurs, respectively. For larger particles, the optimal loading of dopants is rather wide, and for smaller particles it gets smaller. No optimal solution can be obtained for particles below the critical size (2.8 nm for ZnO and 3.2 nm for TiO₂). The plotting of the experimentally determined data into the graph clearly shows a good agreement

with the theory. There is no dependence between the material and the optimum dopant loading, which can be calculated using the following equation [500].

$$r_{\rm d,opt} \approx \frac{6M}{N_{\rm A}\rho\pi d^2} (2.40 \text{ nm}^{-1})$$

Where, $r_{d,opt}$ is the optimum doping ratio, M is the molar mass, N_A is the Avogadro number, ρ is density of the material and d the particle diameter. This calculation is based on the assumption that individual semiconductor particles contain 2.4 dopant atoms for each nanometer of particle diameter. A good agreement of the calculated optimal doping ratio with the experimentally determined values was observed. Hence, this model allows, for the first time, to calculate the optimal doping concentration for a particular material and a given particle size.

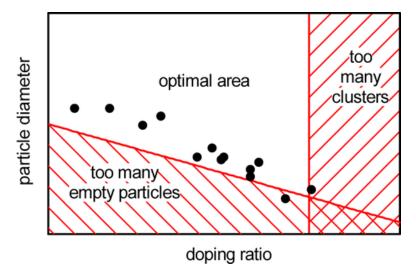


Figure 41. Optimal combinations of particle size and doping ratio. Reproduced with permission from ref. [500] Copyright 2012 American Chemical Society

As mentioned earlier, visible-light photocatalytic activity of cation doped TiO₂ was limited due to the formation of electron hole recombination centers. In addition, recent studies proved that non-metal or metalloids doped TiO₂ materials are much promising than metal-doped counterparts [1,2,17,501-506]. A number of recent reviews also address the use of modified TiO₂ for various environmental

applications. $^{507-512}$ It is clear that the future development of visible-light active TiO_2 would mainly be based on anion doping. The main shortcoming of anion doped TiO₂ is the formation of oxygen vacancies that accelerate the recombination of photo-excited electron-hole pairs. The photocatalytic activity can be significantly improved by reducing the recombination rate of photoexcited electron-hole pairs. This can be pursued through different approaches. For instance, co-doping of TiO₂ is efficient in reducing the formation of compensating oxygen vacancies with a positive effect on the photocatalytic performance of the material. Alternatively, one may combine anion doped TiO₂ with small band gap semiconductors to improve electron-hole separation. Coupling of anion-doped anatase TiO₂ with WO₃, Fe₂O₃ and V₂O₅ (which has less negative conduction band level compared to anatase) can effectively trap photo-excited electrons and thereby reducing electron-hole recombination. Metal nanoparticles (Au, Ag, Pt, Pd etc.) can also be employed as photo-excited electron trap and thereby increasing the photocatalytic performance [63]. Due to the different conduction band energy levels of anatase, rutile and brookite phases, anion-doped multiphase TiO₂ is highly recommended over single phase photocatalyst. This would enable the efficient electron transfer from the conduction band of brookite to anatase, brookite to rutile and anatase to rutile, which can lead to a momentous enhancement in the photocatalytic activity [11, 17, 19].

Coupling of anionic doped TiO₂ with sensitizers such as graphene and carbon nanotubes, is highly recommended considering the fact that these visible-light absorbing carbonaceous dopants can sensitize TiO₂ and separate photogenerated electron-hole pairs. Modification of anion-doped TiO₂ with quantum dots could be very useful for significantly improving the visible-light photocatalytic activity. Semiconductor and noble metal quantum dots can simultaneously sensitize TiO₂

through LSPR and act as electron-hole separating agents. In addition, coupling of anion doped TiO₂ with multiple sensitizers and electron-hole separating agents could be effective for utilizing the whole visible spectrum. Since the photocatalytic activity of TiO₂ highly depends on the particle size, morphology and amount of exposed (001) crystal planes, it is highly recommended to optimize these parameters of anion doped TiO₂ to attain the best results.

Investigation of the electronic structure through DFT calculations can play a fundamental role in the study of these new generation composite photocatalysts. Through these types of calculations it is possible to determine how the band structure is modified when different materials are put into contact to create oxide/oxide, metal/oxide, QD/oxide or sensitizers/oxide heterojunctions for an efficient visible-light absorption and subsequent charge separation at the interface. Theoretical modelling provides solid basis for identifying the key factors into play and for controlling the heterojunctions performance through band structure engineering. Such investigations can be used for predicting novel efficient photocatalytic systems and for improving the existing ones, in the continuous attempt to enhance the control of the structure-properties relationship of materials for photocatalytic applications.

7. Conclusions

Titanium dioxide has been the focus of research efforts in the area of photocatalysis due to its improved chemical stability and high redox potential over other semiconductor photocatalysts. Improving the visible-light spectral sensitivity of TiO₂ is one of the key challenges faced by the community involved in the research of photocatalysts. Recent developments in the area of TiO₂ photocatalysts were promising enough for the development of TiO₂ active in the visible-light region of the

electromagnetic spectrum. A number of techniques have been employed by previous researchers to overcome the main shortcoming of TiO₂ photocatalyst, the poor visiblelight induced photocatalytic activity. In this review, various strategies activation of TiO₂ photocatalysts under visible-light irradiation was discussed in detail. The effect of various visible-light activation techniques on the electronic structure and photocatalytic activities of TiO₂ was critically investigated. Recent theoretical developments explaining the electronic structure of visible-light active TiO₂ were explored. Previous studies demonstrated the fact that various non-metal doped TiO₂ materials are more promising than metal doped counterparts. Each anionic dopant was found to have a distinctive consequence on the electronic structure and photocatalytic activities of TiO₂. The main drawback of the non-metal-doped TiO₂ is the increased carrier recombination, which makes them considerably less active under visible-light than UV-light. Since the synthesis methods, dopant concentration and phase purity crucially affect the photocatalytic activity of TiO₂, further optimization of these parameters are necessary for increasing the visible-light performance of anion-doped TiO₂. Another vital challenge is the fabrication of thermally stable TiO₂ with predictable performance under visible and UV-light. Since the charge carrier recombination is the major drawback of current generation anion-doped TiO2, future research should be devoted for enhancing the lifetime of electron-hole pairs. The advancements made to date in the area of visible-light activated TiO₂ photocatalysts are encouraging and further widens its scope of applications in environmental protection. A number of recommendations for enhancing the photocatalytic performance of the current generation visible-light active TiO₂ are also presented.

Acknowledgements

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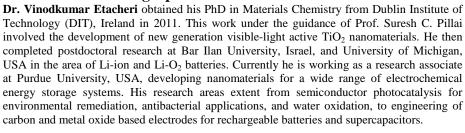
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